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Datasheet

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3	□5	h	-	5	2	5	9	□
3	□6	h	.	.	.	-	h	5	F	5	9	□
3	□7	h	h	4	□	0
3	□8	h	.	h	4	□	0
3	□9	D	h	4	□	...	0	...
3	□2	h	0	4	□	0
4	□5	4	□	..	2	...
4	□	h	1	4	□	..	2	...
4	□	h	2	4	□	..	2	...
4	□	h	3	4	□	..	4	...
4	□	h	4	5	□
4	□	h	5	5	□
4	□	h	6	5	□
4	□	h	7	5	□
4	□	h	8	5	□
4	□	h	9	6	□
4	□	h	0	5	□
4	□	h	1	5	□
4	□	h	2	8	□
4	□	h	3	5	6	□	...	0	...
4	□	h	4	6	□	..	1	...
4	□	D	5	h	6	□	...	1	...
4	□	h	6	5	6	□	..	3	...
4	□	h	7	6	□	..	3	...
4	□	h	8	5	6	□	..	4	...
4	□	h	9	6	□	..	4	...
4	□	h	2	0	6	□	...	5	...
4	□	h	2	F	1	5	6	□	..	5	...
4	□	h	2	2	6	□	..	6	...
4	□	h	2	3	6	□	..	9	...
4	□	h	2	4	0	□
4	□	h	2	5	0	□



5	□	□	□	□	7	□
5	□	□	□	0	□	7.1	□
5	□	□	□	4	□	7.2	□
5	□	□	□	8	□	7.3	□
5	□	□	□	□	□	7.4	□
5	□	□	□	□	□	7.5	□
6	□	□	□	8	□
7	□	□	□	8.1	□

1

3

The GD32E103xx device belongs to the connectivity line of GD32 MCU Family. It is a 32-bit general-purpose microcontroller based on the ARM® Cortex®-M4 RISC core with best cost-performance ratio in terms of enhanced processing capacity, reduced power consumption and peripheral set. The Cortex-M4 core features implements a full set of DSP instructions to address digital signal control markets that demand an efficient, easy-to-use blend of control and signal processing capabilities. It also provides powerful trace technology for enhanced application security and advanced debug support.

The GD32E103xx device incorporates the ARM® Cortex®-M4 32-bit processor core operating at 120 MHz frequency with Flash accesses zero wait states to obtain maximum efficiency. It provides up to 128 KB on-chip Flash memory and 32 KB SRAM memory. An extensive range of enhanced I/Os and peripherals connected to two APB buses. The devices offer up to two 12-bit 3 MSPS ADCs, two 12-bit DACs, up to ten general 16-bit timers, two 16-bit PWM advanced timers, and two 16-bit basic timers, as well as standard and advanced communication interfaces: up to three SPIs, two I2Cs, three USARTs and two UARTs, two I2Ss, an USBFS and two CANs.

The device operates from 1.71 to 3.6 V power supply and available in -40 to +85 °C temperature range. Several power saving modes provide the flexibility for maximum optimization between wakeup latency and power consumption, an especially important consideration in low power applications.

The above features make GD32E103xx devices suitable for a wide range of interconnection and advanced applications, especially in areas such as industrial control, motor drives, consumer and handheld equipment, human machine interface, security and alarm systems, POS, automotive navigation, IoT and so on.



2 . D iv

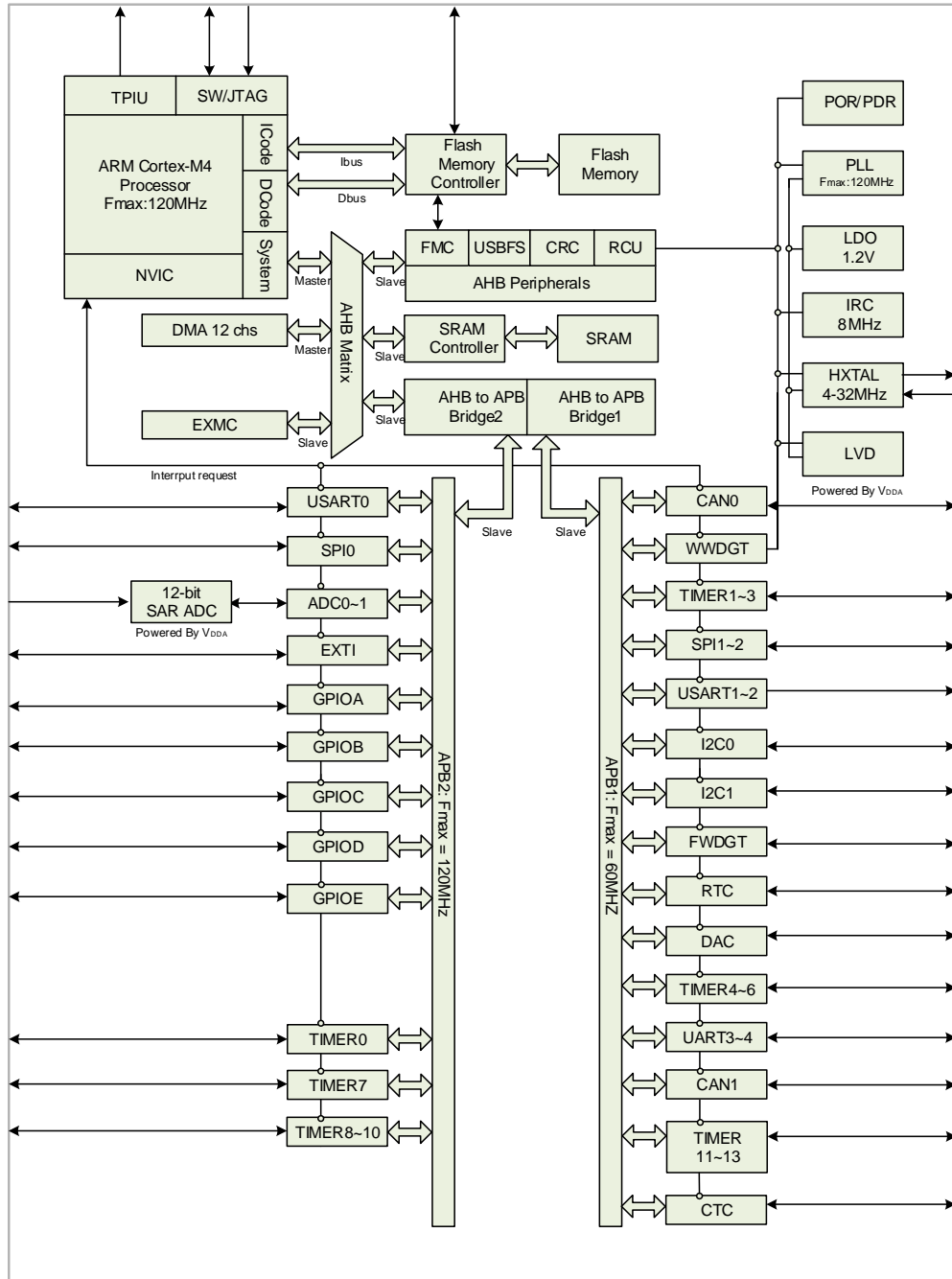
2 . D 1 in

Table 2-1. D 2 pin list

Pin		Signal							
		I/O	B	C	B	R	B	Y	VB
F 0 E		64	128	64	128	64	128	64	128
E 0)		20	32	20	32	20	32	20	32
Pin	G 0 (- p	4 (1-4)	4 (1-4)	10 (1-4,8-13)	10 (1-4,8-13)	10 (1-4,8-13)	10 (1-4,8-13)	10 (1-4,8-13)	10 (1-4,8-13)
	A in (-p 6	1 (0)	1 (0)	1 (0)	1 (0)	2 (0,7)	2 (0,7)	2 (0,7)	2 (0,7)
	B	1	1	1	1	1	1	1	1
	B 0 (-p 6	2 (5,6)	2 (5,6)	2 (5,6)	2 (5,6)	2 (5,6)	2 (5,6)	2 (5,6)	2 (5,6)
	W	2	2	2	2	2	2	2	2
	E	1	1	1	1	1	1	1	1
Pin	E	2 (0-1)	2 (0-1)	3 (0-2)	3 (0-2)	3 (0-2)	3 (0-2)	3 (0-2)	3 (0-2)
	UR	0	0	0	0	2 (3-4)	2 (3-4)	2 (3-4)	2 (3-4)
	2 C	1 (0)	1 (0)	2 (0-1)	2 (0-1)	2 (0-1)	2 (0-1)	2 (0-1)	2 (0-1)
	B 2 S	1/0 (0-)	1/0 (0-)	3/2 (0-2)/(1-2)	3/2 (0-2)/(1-2)	3/2 (0-2)/(1-2)	3/2 (0-2)/(1-2)	3/2 (0-2)/(1-2)	3/2 (0-2)/(1-2)
	E	2xFD	2xFD	2xFD	2xFD	2xFD	2xFD	2xFD	2xFD
	B F S	1	1	1	1	1	1	1	1
E		26	26	37	37	51	51	80	80
E		0	0	0	0	0	0	1	1
E		16	16	16	16	16	16	16	16
Pin	E	2	2	2	2	2	2	2	2
	E	10	10	10	10	16	16	16	16
D E		2	2	2	2	2	2	2	2
Package		QFN36		LQFP48		LQFP64		LQFP100	

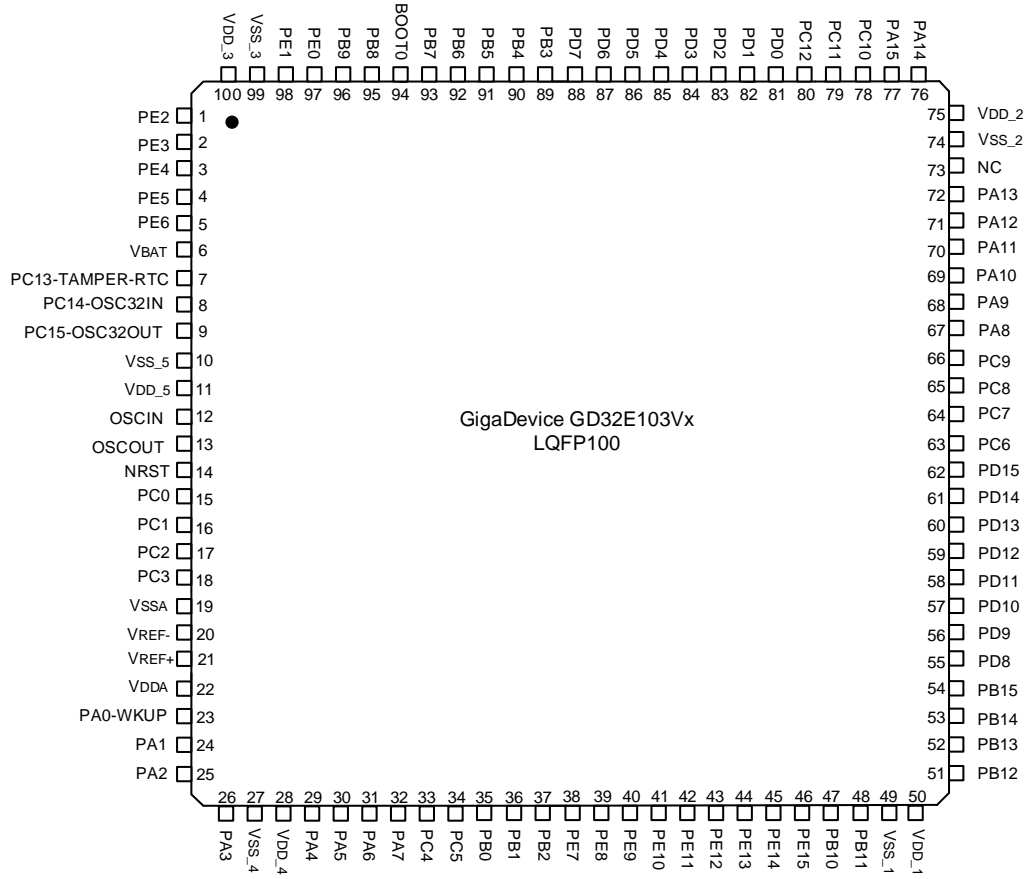
2 . B 2 th .

F 图 1-10 图 2 xx 图 3

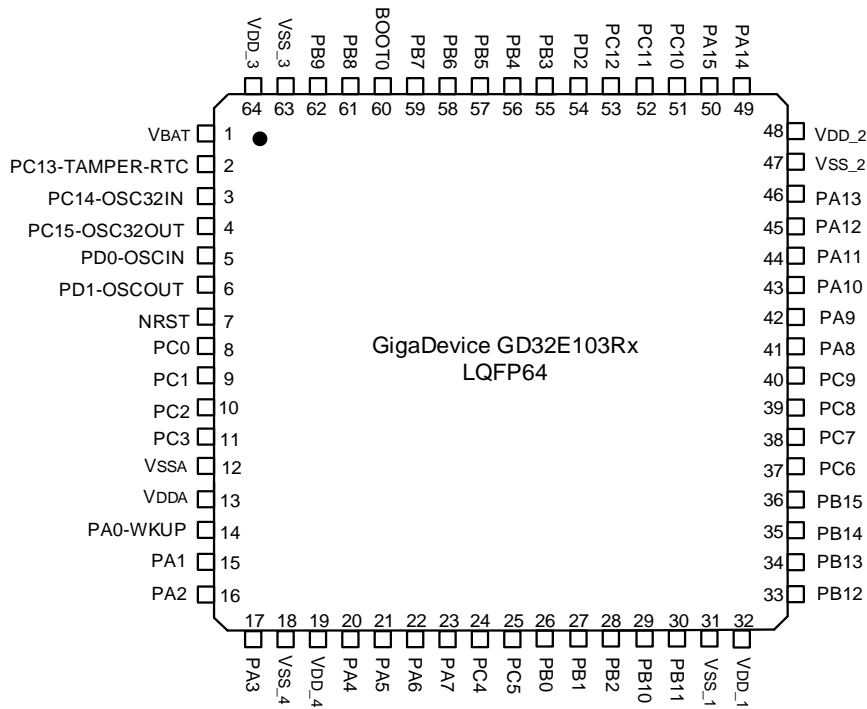


2 . 3

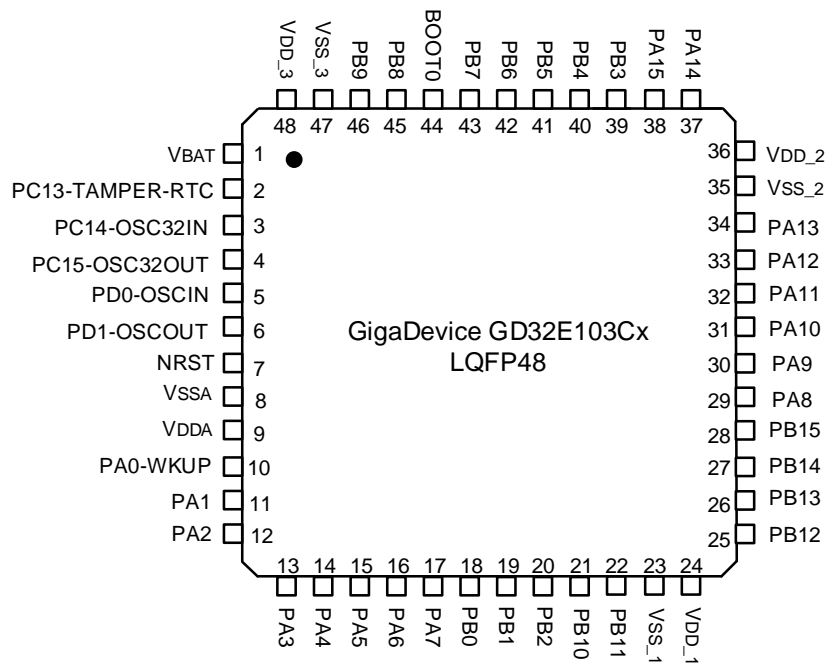
F 2- D 2 E P 0



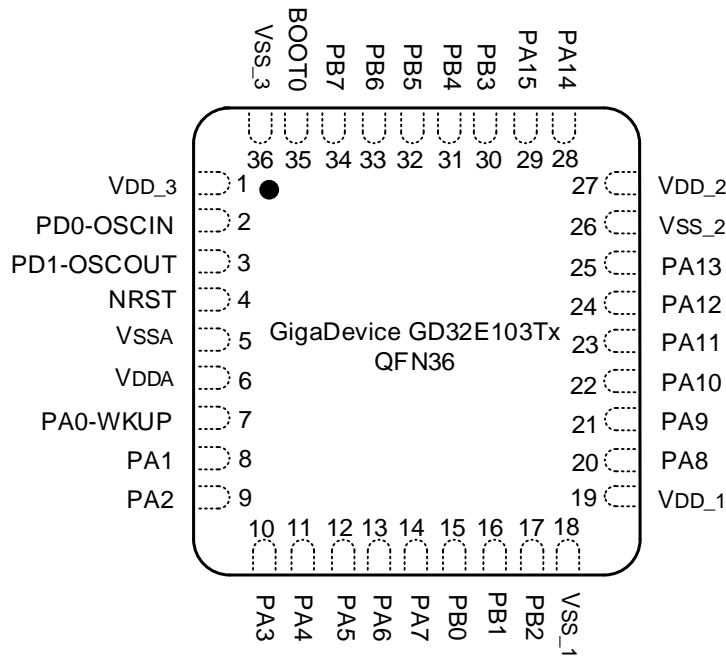
F 3- G 2 E PD P 4



F 4- G 2 E PD P 8



F 2-5. 2 2 E P D 2



2 . M 4 .

2-2. 2 xx 3

Address Range	Bus	Device	Function
0xA000 0000 - 0xA000 0FFF	AHB3	External device	EXMC - SWREG
0x9000 0000 - 0x9FFF FFFF			Reserved
0x7000 0000 - 0x8FFF FFFF			Reserved
0x6000 0000 - 0x63FF FFFF			EXMC - NOR/PSRAM/SRAM
0x5000 0000 - 0x5003 FFFF	AHB1	Peripheral	USBFS
0x4008 0000 - 0x4FFF FFFF			Reserved
0x4004 0000 - 0x4007 FFFF			Reserved
0x4002 BC00 - 0x4003 FFFF			Reserved
0x4002 B000 - 0x4002 BBFF			Reserved
0x4002 A000 - 0x4002 AFFF			Reserved
0x4002 8000 - 0x4002 9FFF			Reserved
0x4002 6800 - 0x4002 7FFF			Reserved
0x4002 6400 - 0x4002 67FF			Reserved
0x4002 6000 - 0x4002 63FF			Reserved
0x4002 5000 - 0x4002 5FFF			Reserved
0x4002 4000 - 0x4002 4FFF			Reserved
0x4002 3C00 - 0x4002 3FFF			Reserved

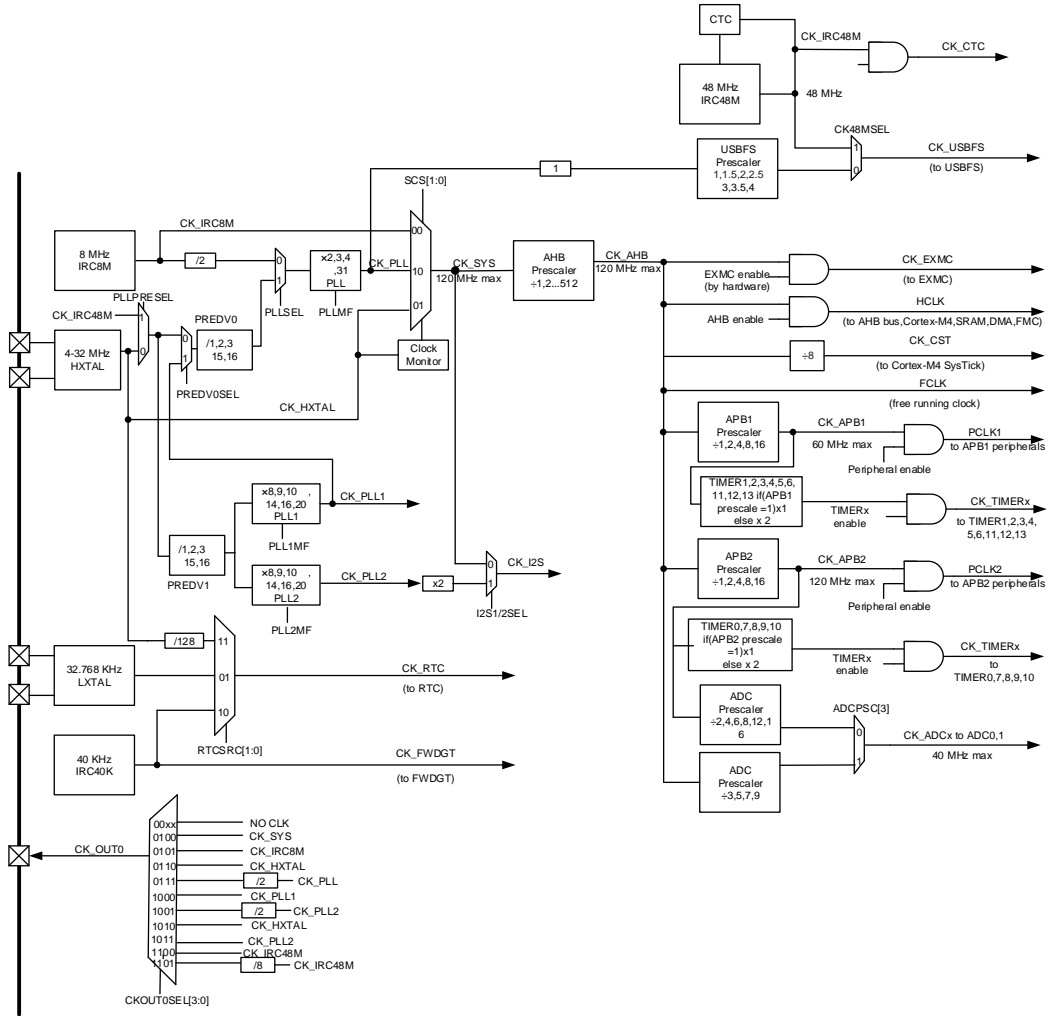
Address	Block	Device	Function
0x4002 3800 - 0x4002 3BFF			Reserved
0x4002 3400 - 0x4002 37FF			Reserved
0x4002 3000 - 0x4002 33FF			CRC
0x4002 2C00 - 0x4002 2FFF			Reserved
0x4002 2800 - 0x4002 2BFF			Reserved
0x4002 2400 - 0x4002 27FF			Reserved
0x4002 2000 - 0x4002 23FF			FMC
0x4002 1C00 - 0x4002 1FFF			Reserved
0x4002 1800 - 0x4002 1BFF			Reserved
0x4002 1400 - 0x4002 17FF			Reserved
0x4002 1000 - 0x4002 13FF			RCU
0x4002 0C00 - 0x4002 0FFF			Reserved
0x4002 0800 - 0x4002 0BFF			Reserved
0x4002 0400 - 0x4002 07FF			DMA1
0x4002 0000 - 0x4002 03FF			DMA0
0x4001 8400 - 0x4001 FFFF			Reserved
0x4001 8000 - 0x4001 83FF	Reserved		
0x4001 7C00 - 0x4001 7FFF	APB2	Reserved	
0x4001 7800 - 0x4001 7BFF		Reserved	
0x4001 7400 - 0x4001 77FF		Reserved	
0x4001 7000 - 0x4001 73FF		Reserved	
0x4001 6C00 - 0x4001 6FFF		Reserved	
0x4001 6800 - 0x4001 6BFF		Reserved	
0x4001 5C00 - 0x4001 67FF		Reserved	
0x4001 5800 - 0x4001 5BFF		Reserved	
0x4001 5400 - 0x4001 57FF		TIMER10	
0x4001 5000 - 0x4001 53FF		TIMER9	
0x4001 4C00 - 0x4001 4FFF		TIMER8	
0x4001 4800 - 0x4001 4BFF		Reserved	
0x4001 4400 - 0x4001 47FF		Reserved	
0x4001 4000 - 0x4001 43FF		Reserved	
0x4001 3C00 - 0x4001 3FFF		Reserved	
0x4001 3800 - 0x4001 3BFF		USART0	
0x4001 3400 - 0x4001 37FF		TIMER7	
0x4001 3000 - 0x4001 33FF		SPI0	
0x4001 2C00 - 0x4001 2FFF		TIMER0	
0x4001 2800 - 0x4001 2BFF		ADC1	
0x4001 2400 - 0x4001 27FF	ADC0		
0x4001 2000 - 0x4001 23FF	Reserved		

Address Range	Block	Address	Peripheral	
		0x4001 1C00 - 0x4001 1FFF	Reserved	
		0x4001 1800 - 0x4001 1BFF	GPIOE	
		0x4001 1400 - 0x4001 17FF	GPIOD	
		0x4001 1000 - 0x4001 13FF	GPIOC	
		0x4001 0C00 - 0x4001 0FFF	GPIOB	
		0x4001 0800 - 0x4001 0BFF	GPIOA	
		0x4001 0400 - 0x4001 07FF	EXTI	
		0x4001 0000 - 0x4001 03FF	AFIO	
	APB1		0x4000 CC00 - 0x4000 FFFF	Reserved
			0x4000 C800 - 0x4000 CBFF	CTC
			0x4000 C400 - 0x4000 C7FF	Reserved
			0x4000 C000 - 0x4000 C3FF	Reserved
			0x4000 8000 - 0x4000 BFFF	Reserved
			0x4000 7C00 - 0x4000 7FFF	Reserved
			0x4000 7800 - 0x4000 7BFF	Reserved
			0x4000 7400 - 0x4000 77FF	DAC
			0x4000 7000 - 0x4000 73FF	PMU
			0x4000 6C00 - 0x4000 6FFF	BKP
			0x4000 6800 - 0x4000 6BFF	CAN1
			0x4000 6400 - 0x4000 67FF	CAN0
			0x4000 6000 - 0x4000 63FF	CAN SRAM 1K bytes
			0x4000 5C00 - 0x4000 5FFF	Reserved
			0x4000 5800 - 0x4000 5BFF	I2C1
			0x4000 5400 - 0x4000 57FF	I2C0
			0x4000 5000 - 0x4000 53FF	UART4
			0x4000 4C00 - 0x4000 4FFF	UART3
			0x4000 4800 - 0x4000 4BFF	USART2
			0x4000 4400 - 0x4000 47FF	USART1
0x4000 4000 - 0x4000 43FF	Reserved			
0x4000 3C00 - 0x4000 3FFF	SPI2/I2S2			
0x4000 3800 - 0x4000 3BFF	SPI1/I2S1			
0x4000 3400 - 0x4000 37FF	Reserved			
0x4000 3000 - 0x4000 33FF	FWDGT			
0x4000 2C00 - 0x4000 2FFF	WWDGT			
0x4000 2800 - 0x4000 2BFF	RTC			
0x4000 2400 - 0x4000 27FF	Reserved			
0x4000 2000 - 0x4000 23FF	TIMER13			
0x4000 1C00 - 0x4000 1FFF	TIMER12			
0x4000 1800 - 0x4000 1BFF	TIMER11			

Address Range	Bus	Address	Device
		0x4000 1400 - 0x4000 17FF	TIMER6
		0x4000 1000 - 0x4000 13FF	TIMER5
		0x4000 0C00 - 0x4000 0FFF	TIMER4
		0x4000 0800 - 0x4000 0BFF	TIMER3
		0x4000 0400 - 0x4000 07FF	TIMER2
		0x4000 0000 - 0x4000 03FF	TIMER1
SRAM	AHB	0x2007 0000 - 0x3FFF FFFF	Reserved
		0x2006 0000 - 0x2006 FFFF	Reserved
		0x2003 0000 - 0x2005 FFFF	Reserved
		0x2002 0000 - 0x2002 FFFF	Reserved
		0x2001 C000 - 0x2001 FFFF	SRAM
		0x2001 8000 - 0x2001 BFFF	
		0x2000 5000 - 0x2001 7FFF	
		0x2000 0000 - 0x2000 4FFF	
Code	AHB	0x1FFF F810 - 0x1FFF FFFF	Reserved
		0x1FFF F800 - 0x1FFF F80F	Option Bytes
		0x1FFF F000 - 0x1FFF F7FF	Boot loader
		0x1FFF C010 - 0x1FFF EFFF	
		0x1FFF C000 - 0x1FFF C00F	
		0x1FFF B000 - 0x1FFF BFFF	
		0x1FFF 7A10 - 0x1FFF AFFF	Reserved
		0x1FFF 7800 - 0x1FFF 7A0F	Reserved
		0x1FFF 0000 - 0x1FFF 77FF	Reserved
		0x1FFE C010 - 0x1FFE FFFF	Reserved
		0x1FFE C000 - 0x1FFE C00F	Reserved
		0x1001 0000 - 0x1FFE BFFF	Reserved
		0x1000 0000 - 0x1000 FFFF	Reserved
		0x083C 0000 - 0x0FFF FFFF	Reserved
		0x0830 0000 - 0x083B FFFF	Reserved
		0x0810 0000 - 0x082F FFFF	Main Flash
		0x0802 0000 - 0x080F FFFF	
		0x0800 0000 - 0x0801 FFFF	
		0x0030 0000 - 0x07FF FFFF	Reserved
		0x0010 0000 - 0x002F FFFF	Aliased to Main Flash or Boot loader
		0x0002 0000 - 0x000F FFFF	
		0x0000 0000 - 0x0001 FFFF	

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F 5-6. D 2 xx 3



- HXTAL: 4 to 32 MHz High Speed crystal oscillator
- LXTAL: 32,768 Hz Low Speed crystal oscillator
- IRC8M: Internal 8 MHz RC oscillator
- IRC40K: Internal 40 KHz RC oscillator
- IRC48M: Internal 48 MHz RC oscillator

2 . 6

For GD32E103Rx LQFP64 GD32E103Cx LQFP48 and GD32E103Tx QFN36, V_{REF-} and V_{REF+} are internally connected to V_{SSA} and V_{DDA} respectively.

2. 6. E20V x 0
5 2-3. 0 2 0 0

Pin	Pin	Function	Supply	Default / Alternate
PE2	1	I/O	5VT	Default: PE2 Alternate: TRACECK, EXMC_A23
PE3	2	I/O	5VT	Default: PE3 Alternate: TRACED0, EXMC_A19
PE4	3	I/O	5VT	Default: PE4 Alternate: TRACED1, EXMC_A20
PE5	4	I/O	5VT	Default: PE5 Alternate: TRACED2, EXMC_A21 Remap: TIMER8_CH0
PE6	5	I/O	5VT	Default: PE6 Alternate: TRACED3, EXMC_A22 Remap: TIMER8_CH1
V _{BAT}	6	P	-	Default: V _{BAT}
PC13-TAMPER-RTC	7	I/O	-	Default: PC13 Alternate: RTC_TAMPER
PC14-OSC32IN	8	I/O	-	Default: PC14 Alternate: OSC32IN
PC15-OSC32OUT	9	I/O	-	Default: PC15 Alternate: OSC32OUT
V _{SS_5}	10	P	-	Default: V _{SS_5}
V _{DD_5}	11	P	-	Default: V _{DD_5}
OSCIN	12	I	-	Default: OSCIN Remap: PD0
OSCOUT	13	O	-	Default: OSCOUT Remap: PD1
NRST	14	I/O	-	Default: NRST
PC0	15	I/O	-	Default: PC0 Alternate: ADC01_IN10
PC1	16	I/O	-	Default: PC1 Alternate: ADC01_IN11
PC2	17	I/O	-	Default: PC2 Alternate: ADC01_IN12
PC3	18	I/O	-	Default: PC3 Alternate: ADC01_IN13
V _{SSA}	19	P	-	Default: V _{SSA}
V _{REF-}	20	P	-	Default: V _{REF-}

Pin	Pin No.	Mode	IO Type	Function
V _{REF+}	21	P	-	Default: V _{REF+}
V _{DDA}	22	P	-	Default: V _{DDA}
PA0-WKUP	23	I/O	-	Default: PA0 Alternate: WKUP, USART1_CTS, ADC01_IN0, TIMER1_CH0, TIMER1_ETI, TIMER4_CH0, TIMER7_ETI
PA1	24	I/O	-	Default: PA1 Alternate: USART1_RTS, ADC01_IN1, TIMER4_CH1, TIMER1_CH1
PA2	25	I/O	-	Default: PA2 Alternate: USART1_TX, TIMER4_CH2, ADC01_IN2, TIMER8_CH0, TIMER1_CH2, SPI0_IO2
PA3	26	I/O	-	Default: PA3 Alternate: USART1_RX, TIMER4_CH3, ADC01_IN3, TIMER1_CH3, TIMER8_CH1, SPI0_IO3
V _{SS_4}	27	P	-	Default: V _{SS_4}
V _{DD_4}	28	P	-	Default: V _{DD_4}
PA4	29	I/O	-	Default: PA4 Alternate: SPI0_NSS, USART1_CK, DAC_OUT0, ADC01_IN4 Remap: SPI2_NSS, I2S2_WS
PA5	30	I/O	-	Default: PA5 Alternate: SPI0_SCK, ADC01_IN5, DAC_OUT1
PA6	31	I/O	-	Default: PA6 Alternate: SPI0_MISO, TIMER7_BRKIN, ADC01_IN6, TIMER2_CH0, TIMER12_CH0 Remap: TIMER0_BRKIN
PA7	32	I/O	-	Default: PA7 Alternate: SPI0_MOSI, TIMER7_CH0_ON, ADC01_IN7, TIMER2_CH1, TIMER13_CH0 Remap: TIMER0_CH0_ON
PC4	33	I/O	-	Default: PC4 Alternate: ADC01_IN14
PC5	34	I/O	-	Default: PC5 Alternate: ADC01_IN15
PB0	35	I/O	-	Default: PB0 Alternate: ADC01_IN8, TIMER2_CH2, TIMER7_CH1_ON Remap: TIMER0_CH1_ON
PB1	36	I/O	-	Default: PB1 Alternate: ADC01_IN9, TIMER2_CH3, TIMER7_CH2_ON Remap: TIMER0_CH2_ON
PB2	37	I/O	5VT	Default: PB2, BOOT1

Pin	Port	Mode	Supply	Function
PE7	38	I/O	5VT	Default: PE7 Alternate: EXMC_D4 Remap: TIMER0_ET1
PE8	39	I/O	5VT	Default: PE8 Alternate: EXMC_D5 Remap: TIMER0_CH0_ON
PE9	40	I/O	5VT	Default: PE9 Alternate: EXMC_D6 Remap: TIMER0_CH0
PE10	41	I/O	5VT	Default: PE10 Alternate: EXMC_D7 Remap: TIMER0_CH1_ON
PE11	42	I/O	5VT	Default: PE11 Alternate: EXMC_D8 Remap: TIMER0_CH1
PE12	43	I/O	5VT	Default: PE12 Alternate: EXMC_D9 Remap: TIMER0_CH2_ON
PE13	44	I/O	5VT	Default: PE13 Alternate: EXMC_D10 Remap: TIMER0_CH2
PE14	45	I/O	5VT	Default: PE14 Alternate: EXMC_D11 Remap: TIMER0_CH3
PE15	46	I/O	5VT	Default: PE15 Alternate: EXMC_D12 Remap: TIMER0_BRKIN
PB10	47	I/O	5VT	Default: PB10 Alternate: I2C1_SCL, USART2_TX Remap: TIMER1_CH2
PB11	48	I/O	5VT	Default: PB11 Alternate: I2C1_SDA, USART2_RX Remap: TIMER1_CH3
V _{SS_1}	49	P	-	Default: V _{SS_1}
V _{DD_1}	50	P	-	Default: V _{DD_1}
PB12	51	I/O	5VT	Default: PB12 Alternate: SPI1_NSS, I2S1_WS, I2C1_SMBA, USART2_CK, TIMER0_BRKIN, CAN1_RX
PB13	52	I/O	5VT	Default: PB13 Alternate: SPI1_SCK, I2S1_CK, USART2_CTS, TIMER0_CH0_ON, CAN1_TX, I2C1_TXFRAME

Pin	Pin No.	Function	Supply Voltage	Alternate Functions
PB14	53	I/O	5VT	Default: PB14 Alternate: SPI1_MISO, USART2_RTS, TIMER0_CH1_ON, TIMER11_CH0
PB15	54	I/O	5VT	Default: PB15 Alternate: SPI1_MOSI, I2S1_SD, TIMER0_CH2_ON, TIMER11_CH11
PD8	55	I/O	5VT	Default: PD8 Alternate: EXMC_D13 Remap: USART2_TX
PD9	56	I/O	5VT	Default: PD9 Alternate: EXMC_D14 Remap: USART2_RX
PD10	57	I/O	5VT	Default: PD10 Alternate: EXMC_D15 Remap: USART2_CK
PD11	58	I/O	5VT	Default: PD11 Alternate: EXMC_A16 Remap: USART2_CTS
PD12	59	I/O	5VT	Default: PD12 Alternate: EXMC_A17 Remap: TIMER3_CH0, USART2_RTS
PD13	60	I/O	5VT	Default: PD13 Alternate: EXMC_A18 Remap: TIMER3_CH1
PD14	61	I/O	5VT	Default: PD14 Alternate: EXMC_D0 Remap: TIMER3_CH2
PD15	62	I/O	5VT	Default: PD15 Alternate: EXMC_D1 Remap: TIMER3_CH3, CTC_SYNC
PC6	63	I/O	5VT	Default: PC6 Alternate: I2S1_MCK, TIMER7_CH0 Remap: TIMER2_CH0
PC7	64	I/O	5VT	Default: PC7 Alternate: I2S2_MCK, TIMER7_CH1 Remap: TIMER2_CH1
PC8	65	I/O	5VT	Default: PC8 Alternate: TIMER7_CH2 Remap: TIMER2_CH2

Pin	Pin No.	Direction	Supply	Function
PC9	66	I/O	5VT	Default: PC9 Alternate: TIMER7_CH3 Remap: TIMER2_CH3
PA8	67	I/O	5VT	Default: PA8 Alternate: USART0_CK, TIMER0_CH0, CK_OUT0, VCORE, USBFS_SOF, CTC_SYNC
PA9	68	I/O	5VT	Default: PA9 Alternate: USART0_TX, TIMER0_CH1, USBFS_VBUS
PA10	69	I/O	5VT	Default: PA10 Alternate: USART0_RX, TIMER0_CH2, USBFS_ID, V1REF
PA11	70	I/O	5VT	Default: PA11 Alternate: USART0_CTS, CAN0_RX, USBFS_DM, TIMER0_CH3
PA12	71	I/O	5VT	Default: PA12 Alternate: USART0_RTS, CAN0_TX, USBFS_DP, TIMER0_ETI
PA13	72	I/O	5VT	Default: JTMS, SWDIO Remap: PA13
NC	73	-	-	-
V _{SS_2}	74	P	-	Default: V _{SS_2}
V _{DD_2}	75	P	-	Default: V _{DD_2}
PA14	76	I/O	5VT	Default: JTCK, SWCLK Remap: PA14
PA15	77	I/O	5VT	Default: JTDI Alternate: SPI2_NSS, I2S2_WS Remap: TIMER1_CH0, TIMER1_ETI, PA15, SPI0_NSS
PC10	78	I/O	5VT	Default: PC10 Alternate: UART3_TX Remap: USART2_TX, SPI2_SCK, I2S2_CK
PC11	79	I/O	5VT	Default: PC11 Alternate: UART3_RX Remap: USART2_RX, SPI2_MISO
PC12	80	I/O	5VT	Default: PC12 Alternate: UART4_TX Remap: USART2_CK, SPI2_MOSI, I2S2_SD
PD0	81	I/O	5VT	Default: PD0 Alternate: EXMC_D2 Remap: OSCIN,

Pin	Port	Mode	Drive	Function
PD2	83	I/O	5VT	Default: PD2 Alternate: TIMER2_ETI, UART4_RX
PD3	84	I/O	5VT	Default: PD3 Alternate: EXMC_CLK Remap: USART1_CTS
PD4	85	I/O	5VT	Default: PD4 Alternate: EXMC_NOE Remap: USART1_RTS
PD5	86	I/O	5VT	Default: PD5 Alternate: EXMC_NWE Remap: USART1_TX
PD6	87	I/O	5VT	Default: PD6 Alternate: EXMC_NWAIT Remap: USART1_RX
PD7	88	I/O	5VT	Default: PD7 Alternate: EXMC_NE0 Remap: USART1_CK
PB3	89	I/O	5VT	Default: JTDO Alternate: SPI2_SCK, I2S2_CK Remap: TIMER1_CH1, PB3, TRACESWO, SPI0_SCK
PB4	90	I/O	5VT	Default: NJTRST Alternate: SPI2_MISO, I2C0_TXFRAME Remap: TIMER2_CH0, PB4, SPI0_MISO
PB5	91	I/O	-	Default: PB5 Alternate: I2C0_SMBA, SPI2_MOSI, I2S2_SD Remap: TIMER2_CH1, SPI0_MOSI, CAN1_RX
PB6	92	I/O	5VT	Default: PB6 Alternate: I2C0_SCL, TIMER3_CH0 Remap: USART0_TX, CAN1_TX, SPI0_IO2
PB7	93	I/O	5VT	Default: PB7 Alternate: I2C0_SDA, TIMER3_CH1, EXMC_NL(NADV) Remap: USART0_RX, SPI0_IO3
BOOT0	94	I	-	Default: BOOT0
PB8	95	I/O	5VT	Default: PB8 Alternate: TIMER3_CH2, TIMER9_CH0 Remap: I2C0_SCL, CAN0_RX
PB9	96	I/O	5VT	Default: PB9 Alternate: TIMER3_CH3, TIMER10_CH0 Remap: I2C0_SDA, CAN0_TX
PE0	97	I/O	5VT	Default: PE0 Alternate: TIMER3_ETI, EXMC_NBL0

Pin	Pin No.	Type	Level	Function
PE1	98	I/O	5VT	Default: PE1 Alternate: EXMC_NBL1
V _{SS_3}	99	P	-	Default: V _{SS_3}
V _{DD_3}	100	P	-	Default: V _{DD_3}

Note:

1. Type: I= input, O = output, P = power.
2. I/O Level: 5VT = 5V tolerant.
3. Functions are available in GD32E103xx devices.

2. Pin 2-4

Table 2-4. Pin 2-4

Pin	Pin No.	Type	Level	Function
V _{BAT}	1	P	-	Default: V _{BAT}
PC13-TAMPER-RTC	2	I/O	-	Default: PC13 Alternate: RTC_TAMPER
PC14-OSC32IN	3	I/O	-	Default: PC14 Alternate: OSC32IN
PC15-OSC32OUT	4	I/O	-	Default: PC15 Alternate: OSC32OUT
PD0-OSCIN	5	I	-	Default: OSCIN Remap: PD0 ⁽³⁾
PD1-OSCOU	6	O	-	Default: OSCOUT Remap: PD1 ⁽³⁾
NRST	7	I/O	-	Default: NRST
PC0	8	I/O	-	Default: PC0 Alternate: ADC01_IN10
PC1	9	I/O	-	Default: PC1 Alternate: ADC01_IN11
PC2	10	I/O	-	Default: PC2 Alternate: ADC01_IN12
PC3	11	I/O	-	Default: PC3 Alternate: ADC01_IN13
V _{SSA}	12	P	-	Default: V _{SSA}
V _{DDA}	13	P	-	Default: V _{DDA}
PA0-WKUP	14	I/O	-	Default: PA0 Alternate: WKUP, USART1_CTS, ADC01_IN0, TIMER1_CH0_ETI, TIMER4_CH0, TIMER7_ETI
PA1	15	I/O	-	Default: PA1

Pin	Pin No.	Function	IO Type	Alternate Functions
				Alternate: USART1_RTS, ADC01_IN1, TIMER4_CH1, TIMER1_CH1
PA2	16	I/O	-	Default: PA2 Alternate: USART1_TX, TIMER4_CH2, ADC01_IN2, TIMER8_CH0, TIMER1_CH2, SPI0_IO2
PA3	17	I/O	-	Default: PA3 Alternate: USART1_RX, TIMER4_CH3, ADC01_IN3, TIMER1_CH3, TIMER8_CH1, SPI0_IO3
V _{SS_4}	18	P	-	Default: V _{SS_4}
V _{DD_4}	19	P	-	Default: V _{DD_4}
PA4	20	I/O	-	Default: PA4 Alternate: SPI0_NSS, USART1_CK, DAC_OUT0, ADC01_IN4 Remap: SPI2_NSS, I2S2_WS
PA5	21	I/O	-	Default: PA5 Alternate: SPI0_SCK, ADC01_IN5, DAC_OUT1
PA6	22	I/O	-	Default: PA6 Alternate: SPI0_MISO, TIMER7_BKIN, ADC01_IN6, TIMER2_CH0, TIMER12_CH0 Remap: TIMER0_BKIN
PA7	23	I/O	-	Default: PA7 Alternate: SPI0_MOSI, TIMER7_CH0_ON, ADC01_IN7, TIMER2_CH1, TIMER13_CH0 Remap: TIMER0_CH0_ON
PC4	24	I/O	-	Default: PC4 Alternate: ADC01_IN14
PC5	25	I/O	-	Default: PC5 Alternate: ADC01_IN15
PB0	26	I/O	-	Default: PB0 Alternate: ADC01_IN8, TIMER2_CH2, TIMER7_CH1_ON Remap: TIMER0_CH1_ON
PB1	27	I/O	-	Default: PB1 Alternate: ADC01_IN9, TIMER2_CH3, TIMER7_CH2_ON Remap: TIMER0_CH2_ON
PB2	28	I/O	5VT	Default: PB2, BOOT1
PB10	29	I/O	5VT	Default: PB10 Alternate: I2C1_SCL, USART2_TX Remap: TIMER1_CH2
PB11	30	I/O	5VT	Default: PB11 Alternate: I2C1_SDA, USART2_RX Remap: TIMER1_CH3

Pin	Port	Mode	Drive	Function
VSS_1	31	P	-	Default: VSS_1
VDD_1	32	P	-	Default: VDD_1
PB12	33	I/O	5VT	Default: PB12 Alternate: SPI1_NSS, I2S1_WS, I2C1_SMBA, USART2_CK, TIMER0_BKIN, CAN1_RX
PB13	34	I/O	5VT	Default: PB13 Alternate: SPI1_SCK, I2S1_CK, USART2_CTS, TIMER0_CH0_ON, CAN1_TX, I2C1_TXFRAME
PB14	35	I/O	5VT	Default: PB14 Alternate: SPI1_MISO, USART2_RTS, TIMER0_CH1_ON, TIMER11_CH0
PB15	36	I/O	5VT	Default: PB15 Alternate: SPI1_MOSI, I2S1_SD, TIMER0_CH2_ON, TIMER11_CH11
PC6	37	I/O	5VT	Default: PC6 Alternate: I2S1_MCK, TIMER7_CH0 Remap: TIMER2_CH0
PC7	38	I/O	5VT	Default: PC7 Alternate: I2S2_MCK, TIMER7_CH1 Remap: TIMER2_CH1
PC8	39	I/O	5VT	Default: PC8 Alternate: TIMER7_CH2 Remap: TIMER2_CH2
PC9	40	I/O	5VT	Default: PC9 Alternate: TIMER7_CH3 Remap: TIMER2_CH3
PA8	41	I/O	5VT	Default: PA8 Alternate: USART0_CK, TIMER0_CH0, CK_OUT0, VCORE, USBFS_SOF, CTC_SYNC
PA9	42	I/O	5VT	Default: PA9 Alternate: USART0_TX, TIMER0_CH1, USBFS_VBUS
PA10	43	I/O	5VT	Default: PA10 Alternate: USART0_RX, TIMER0_CH2, USBFS_ID, V1REF
PA11	44	I/O	5VT	Default: PA11 Alternate: USART0_CTS, CAN0_RX, USBFS_DM, TIMER0_CH3
PA12	45	I/O	5VT	Default: PA12 Alternate: USART0_RTS, CAN0_TX, USBFS_DP, TIMER0_ETI
PA13	46	I/O	5VT	Default: JTMS, SWDIO Remap: PA13

Pin	Port	Mode	Drive	Function
V _{SS_2}	47	P	-	Default: V _{SS_2}
V _{DD_2}	48	P	-	Default: V _{DD_2}
PA14	49	I/O	5VT	Default: JTCK, SWCLK Remap: PA14
PA15	50	I/O	5VT	Default: JTDI Alternate: SPI2_NSS, I2S2_WS Remap: TIMER1_CH0_ETI, TIMER1_ETI, PA15, SPI0_NSS
PC10	51	I/O	5VT	Default: PC10 Alternate: UART3_TX Remap: USART2_TX, SPI2_SCK, I2S2_CK
PC11	52	I/O	5VT	Default: PC11 Alternate: UART3_RX Remap: USART2_RX, SPI2_MISO
PC12	53	I/O	5VT	Default: PC12 Alternate: UART4_TX Remap: USART2_CK, SPI2_MOSI, I2S2_SD
PD2	54	I/O	5VT	Default: PD2 Alternate: TIMER2_ETI, UART4_RX
PB3	55	I/O	5VT	Default: JTDO Alternate: SPI2_SCK, I2S2_CK Remap: TIMER1_CH1, PB3, TRACESWO, SPI0_SCK
PB4	56	I/O	5VT	Default: NJTRST Alternate: SPI2_MISO, I2C0_TXFRAME Remap: TIMER2_CH0, PB4, SPI0_MISO
PB5	57	I/O	-	Default: PB5 Alternate: I2C0_SMBA, SPI2_MOSI, I2S2_SD Remap: TIMER2_CH1, SPI0_MOSI, CAN1_RX
PB6	58	I/O	5VT	Default: PB6 Alternate: I2C0_SCL, TIMER3_CH0 Remap: USART0_TX, CAN1_TX, SPI0_IO2
PB7	59	I/O	5VT	Default: PB7 Alternate: I2C0_SDA, TIMER3_CH1 Remap: USART0_RX, SPI0_IO3
BOOT0	60	I	-	Default: BOOT0
PB8	61	I/O	5VT	Default: PB8 Alternate: TIMER3_CH2, TIMER9_CH0 Remap: I2C0_SCL, CAN0_RX
PB9	62	I/O	5VT	Default: PB9 Alternate: TIMER3_CH3, TIMER10_CH0 Remap: I2C0_SDA, CAN0_TX
V _{SS_3}	63	P	-	Default: V _{SS_3}

Pin	Pin No.	Type	IO Level	Default
VDD_3	64	P	-	Default: VDD_3

Notes:

1. Type: I= input, O = output, P = power.
2. I/O Level: 5VT = 5V tolerant.
3. PD0/PD1 cannot be used for EXTI in this package.

2. Pin Configuration

Table 2-5. Pin Configuration

Pin	Pin No.	Type	IO Level	Default
VBAT	1	P	-	Default: VBAT
PC13-TAMPER-RTC	2	I/O	-	Default: PC13 Alternate: RTC_TAMPER
PC14-OSC32IN	3	I/O	-	Default: PC14 Alternate: OSC32IN
PC15-OSC32OUT	4	I/O	-	Default: PC15 Alternate: OSC32OUT
PD0-OSCIN	5	I	-	Default: OSCIN Remap: PD0 ⁽³⁾
PD1-OSCOUT	6	O	-	Default: OSCOUT Remap: PD1 ⁽³⁾
NRST	7	I/O	-	Default: NRST
VSSA	8	P	-	Default: VSSA
VDDA	9	P	-	Default: VDDA
PA0-WKUP	10	I/O	-	Default: PA0 Alternate: WKUP, USART1_CTS, ADC01_IN0, TIMER1_CH0_ETI, TIMER4_CH0
PA1	11	I/O	-	Default: PA1 Alternate: USART1_RTS, ADC01_IN1, TIMER4_CH1, TIMER1_CH1
PA2	12	I/O	-	Default: PA2 Alternate: USART1_TX, TIMER4_CH2, ADC01_IN2, TIMER8_CH0, TIMER1_CH2, SPI0_IO2
PA3	13	I/O	-	Default: PA3 Alternate: USART1_RX, TIMER4_CH3, ADC01_IN3, TIMER1_CH3, TIMER8_CH1, SPI0_IO3
PA4	14	I/O	-	Default: PA4 Alternate: SPI0_NSS, USART1_CK, DAC_OUT0, ADC01_IN4

Pin	Port	Function	Drive	Notes
				Remap: SPI2_NSS, I2S2_WS
PA5	15	I/O	-	Default: PA5 Alternate: SPI0_SCK, ADC01_IN5, DAC_OUT1
PA6	16	I/O	-	Default: PA6 Alternate: SPI0_MISO, ADC01_IN6, TIMER2_CH0, TIMER12_CH0 Remap: TIMER0_BKIN
PA7	17	I/O	-	Default: PA7 Alternate: SPI0_MOSI, ADC01_IN7, TIMER2_CH1, TIMER13_CH0 Remap: TIMER0_CH0_ON
PB0	18	I/O	-	Default: PB0 Alternate: ADC01_IN8, TIMER2_CH2 Remap: TIMER0_CH1_ON
PB1	19	I/O	-	Default: PB1 Alternate: ADC01_IN9, TIMER2_CH3 Remap: TIMER0_CH2_ON
PB2	20	I/O	5VT	Default: PB2, BOOT1
PB10	21	I/O	5VT	Default: PB10 Alternate: I2C1_SCL, USART2_TX Remap: TIMER1_CH2
PB11	22	I/O	5VT	Default: PB11 Alternate: I2C1_SDA, USART2_RX Remap: TIMER1_CH3
V _{SS_1}	23	P	-	Default: V _{SS_1}
V _{DD_1}	24	P	-	Default: V _{DD_1}
PB12	25	I/O	5VT	Default: PB12 Alternate: SPI1_NSS, I2S1_WS, I2C1_SMBA, USART2_CK, TIMER0_BKIN, CAN1_RX
PB13	26	I/O	5VT	Default: PB13 Alternate: SPI1_SCK, I2S1_CK, USART2_CTS, TIMER0_CH0_ON, CAN1_TX, I2C1_TXFRAME
PB14	27	I/O	5VT	Default: PB14 Alternate: SPI1_MISO, USART2_RTS, TIMER0_CH1_ON, TIMER11_CH0
PB15	28	I/O	5VT	Default: PB15 Alternate: SPI1_MOSI, I2S1_SD, TIMER0_CH2_ON, TIMER11_CH11
PA8	29	I/O	5VT	Default: PA8 Alternate: USART0_CK, TIMER0_CH0, CK_OUT0, VCORE, USBFS_SOF, CTC_SYNC

Pin	Pin No.	Function	Supply	Notes
PA9	30	I/O	5VT	Default: PA9 Alternate: USART0_TX, TIMER0_CH1, USBFS_VBUS
PA10	31	I/O	5VT	Default: PA10 Alternate: USART0_RX, TIMER0_CH2, USBFS_ID, V1REF
PA11	32	I/O	5VT	Default: PA11 Alternate: USART0_CTS, CAN0_RX, USBFS_DM, TIMER0_CH3
PA12	33	I/O	5VT	Default: PA12 Alternate: USART0_RTS, CAN0_TX, USBFS_DP, TIMER0_ETI
PA13	34	I/O	5VT	Default: JTMS, SWDIO Remap: PA13
V _{SS_2}	35	P	-	Default: V _{SS_2}
V _{DD_2}	36	P	-	Default: V _{DD_2}
PA14	37	I/O	5VT	Default: JTCK, SWCLK Remap: PA14
PA15	38	I/O	5VT	Default: JTDI Alternate: SPI2_NSS, I2S2_WS Remap: TIMER1_CH0_ETI, TIMER1_ETI, PA15, SPI0_NSS
PB3	39	I/O	5VT	Default: JTDO Alternate: SPI2_SCK, I2S2_CK Remap: TIMER1_CH1, PB3, TRACESWO, SPI0_SCK
PB4	40	I/O	5VT	Default: NJTRST Alternate: SPI2_MISO, I2C0_TXFRAME Remap: TIMER2_CH0, PB4, SPI0_MISO
PB5	41	I/O	-	Default: PB5 Alternate: I2C0_SMBA, SPI2_MOSI, I2S2_SD Remap: TIMER2_CH1, SPI0_MOSI, CAN1_RX
PB6	42	I/O	5VT	Default: PB6 Alternate: I2C0_SCL, TIMER3_CH0 Remap: USART0_TX, CAN1_TX, SPI0_IO2
PB7	43	I/O	5VT	Default: PB7 Alternate: I2C0_SDA, TIMER3_CH1 Remap: USART0_RX, SPI0_IO3
BOOT0	44	I	-	Default: BOOT0
PB8	45	I/O	5VT	Default: PB8 Alternate: TIMER3_CH2, TIMER9_CH0 Remap: I2C0_SCL, CAN0_RX
PB9	46	I/O	5VT	Default: PB9

Pin	Pin No.	Type	IO Level	Alternate Functions
				Alternate: TIMER3_CH3, TIMER10_CH0 Remap: I2C0_SDA, CAN0_TX
V _{SS_3}	47	P	-	Default: V _{SS_3}
V _{DD_3}	48	P	-	Default: V _{DD_3}

Note:

1. Type: I = input, O = output, P = power.
2. I/O Level: 5VT = 5V tolerant.
3. PD0/PD1 cannot be used for EXTI in this package.

2.6.2. I/O Pin Description

2.6.2.1. Port A Pin Description

Pin	Pin No.	Type	IO Level	Alternate Functions
PD0-OSCIN	2	I	-	Default: OSCIN Remap: PD0 ⁽³⁾
PD1-OSCOUT	3	O	-	Default: OSCOUT Remap: PD1 ⁽³⁾
NRST	4	I/O	-	Default: NRST
V _{SSA}	5	P	-	Default: V _{SSA}
V _{DDA}	6	P	-	Default: V _{DDA}
PA0-WKUP	7	I/O	-	Default: PA0 Alternate: WKUP, USART1_CTS, ADC01_IN0, TIMER1_CH0_ETI, TIMER4_CH0
PA1	8	I/O	-	Default: PA1 Alternate: USART1_RTS, ADC01_IN1, TIMER4_CH1, TIMER1_CH1
PA2	9	I/O	-	Default: PA2 Alternate: USART1_TX, TIMER4_CH2, ADC01_IN2, TIMER1_CH2, SPI0_IO2
PA3	10	I/O	-	Default: PA3 Alternate: USART1_RX, TIMER4_CH3, ADC01_IN3, TIMER1_CH3, SPI0_IO3
PA4	11	I/O	-	Default: PA4 Alternate: SPI0_NSS, USART1_CK, DAC_OUT0, ADC01_IN4
PA5	12	I/O	-	Default: PA5 Alternate: SPI0_SCK, ADC01_IN5, DAC_OUT1
PA6	13	I/O	-	Default: PA6 Alternate: SPI0_MISO, ADC01_IN6, TIMER2_CH0 Remap: TIMER0_BKIN

Pin	Pin No.	IO Type	Drive Strength	Function
PA7	14	I/O	-	Default: PA7 Alternate: SPI0_MOSI, ADC01_IN7, TIMER2_CH1 Remap: TIMER0_CH0_ON
PB0	15	I/O	-	Default: PB0 Alternate: ADC01_IN8, TIMER2_CH2 Remap: TIMER0_CH1_ON
PB1	16	I/O	-	Default: PB1 Alternate: ADC01_IN9, TIMER2_CH3 Remap: TIMER0_CH2_ON
PB2	17	I/O	5VT	Default: PB2, BOOT1
V _{SS_1}	18	P	-	Default: V _{SS_1}
V _{DD_1}	19	P	-	Default: V _{DD_1}
PA8	20	I/O	5VT	Default: PA8 Alternate: USART0_CK, TIMER0_CH0, CK_OUT0, VCORE, USBFS_SOF, CTC_SYNC
PA9	21	I/O	5VT	Default: PA9 Alternate: USART0_TX, TIMER0_CH1, USBFS_VBUS
PA10	22	I/O	5VT	Default: PA10 Alternate: USART0_RX, TIMER0_CH2, USBFS_ID, V1REF
PA11	23	I/O	5VT	Default: PA11 Alternate: USART0_CTS, CAN0_RX, USBFS_DM, TIMER0_CH3
PA12	24	I/O	5VT	Default: PA12 Alternate: USART0_RTS, CAN0_TX, USBFS_DP, TIMER0_ETI
PA13	25	I/O	5VT	Default: JTMS, SWDIO Remap: PA13
V _{SS_2}	26	P	-	Default: V _{SS_2}
V _{DD_2}	27	P	-	Default: V _{DD_2}
PA14	28	I/O	5VT	Default: JTCK, SWCLK Remap: PA14
PA15	29	I/O	5VT	Default: JTDI Remap: TIMER1_CH0_ETI, TIMER1_ETI, PA15, SPI0_NSS
PB3	30	I/O	5VT	Default: JTDO Remap: TIMER1_CH1, PB3, TRACESWO, SPI0_SCK
PB4	31	I/O	5VT	Default: NJTRST Alternate: I2C0_TXFRAME

Pin	Pin No.	Type	Level	Function
				Remap: TIMER2_CH0, PB4, SPI0_MISO
PB5	32	I/O	-	Default: PB5 Alternate: I2C0_SMBA Remap: TIMER2_CH1, SPI0_MOSI, CAN1_RX
PB6	33	I/O	5VT	Default: PB6 Alternate: I2C0_SCL, TIMER3_CH0 Remap: USART0_TX, CAN1_TX, SPI0_IO2
PB7	34	I/O	5VT	Default: PB7 Alternate: I2C0_SDA, TIMER3_CH1 Remap: USART0_RX, SPI0_IO3
BOOT0	35	I	-	Default: BOOT0
V _{SS_3}	36	P	-	Default: V _{SS_3}
V _{DD_3}	1	P	-	Default: V _{DD_3}

Legend:

1. Type: I= input, O = output, P = power.
2. I/O Level: 5VT = 5V tolerant.
3. PD0/PD1 cannot be used for EXTI in this package.

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The ARM® Cortex®-M4 processor is a high performance embedded processor with DSP instructions which allow efficient signal processing and complex algorithm execution. It brings an efficient, easy-to-use blend of control and signal processing capabilities to meet the digital signal control markets demand. The processor is highly configurable enabling a wide range of implementations from those requiring floating point operations, memory protection and powerful trace technology to cost sensitive devices requiring minimal area, while delivering outstanding computational performance and an advanced system response to interrupts.

32-bit ARM® Cortex®-M4 processor core

- Up to 120 MHz operation frequency
- Single-cycle multiplication and hardware divider
- Floating Point Unit (FPU)
- Integrated DSP instructions
- Integrated Nested Vectored Interrupt Controller (NVIC)
- 24-bit SysTick timer

The Cortex®-M4 processor is based on the ARMv7-M architecture and supports both Thumb and Thumb-2 instruction sets. Some system peripherals listed below are also provided by Cortex®-M4:

- Internal Bus Matrix connected with ICode bus, DCode bus, system bus, Private Peripheral Bus (PPB) and debug accesses (AHB-AP)
- Nested Vectored Interrupt Controller (NVIC)
- Flash Patch and Breakpoint (FPB)
- Data Watchpoint and Trace (DWT)
- Instrument Trace Macrocell (ITM)
- Serial Wire JTAG Debug Port (SWJ-DP)
- Trace Port Interface Unit (TPIU)

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- Up to 128 Kbytes of Flash memory
- Up to 32 KB of SRAM

The ARM® Cortex®-M4 processor is structured in Harvard architecture which can use separate buses to fetch instructions and load/store data. 128 Kbytes of inner Flash at most, which includes code Flash that available for storing programs and data, and accessed (R/W) at CPU clock speed with zero wait states. An extra data Flash is also included for storing data mainly. [Table 2-2. GD32E103xx memory map](#) shows the memory of the GD32E103xx series of devices, including Flash, SRAM, peripheral, and other pre-defined regions.

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- Internal 8 MHz factory-trimmed RC and external 4 to 32 MHz crystal oscillator
- Internal 48 MHz RC oscillator
- Internal 40 KHz RC calibrated oscillator and external 32.768 KHz crystal oscillator
- 1.71 to 3.6 V application supply and I/Os
- Supply Supervisor: POR (Power On Reset), PDR (Power Down Reset), and low voltage detector (LVD)

The Clock Control Unit (CCU) provides a range of oscillator and clock functions. These include internal RC oscillator and external crystal oscillator, high speed and low speed two types. Several prescalers allow the frequency configuration of the AHB and two APB domains. The maximum frequency of the two AHB domains are 120MHz. The maximum frequency of the two APB domains including APB1 is 60 MHz and APB2 is 120 MHz. See [Figure 2-6. GD32E103xx clock tree](#) for details on the clock tree.

The Reset Control Unit (RCU) controls three kinds of reset: system reset resets the processor core and peripheral IP components. Power-on reset (POR) and power-down reset (PDR) are always active, and ensures proper operation starting from 1.66V/down to 1.62V. The device remains in reset mode when V_{DD} is below a specified threshold. The embedded low voltage detector (LVD) monitors the power supply, compares it to the voltage threshold and generates an interrupt as a warning message for leading the MCU into security.

Power supply schemes:

- V_{DD} range: 1.71 to 3.6 V, external power supply for I/Os and the internal regulator. Provided externally through V_{DD} pins.
- V_{DDA} range: 1.71 to 3.6 V, external analog power supplies for ADC, reset blocks, RCs and PLL. V_{DDA} and V_{SSA} must be connected to V_{DD} and V_{SS} , respectively.
- V_{BAT} range: 1.71 to 3.6 V, power supply for RTC, external clock 32.768 KHz oscillator and backup registers (through power switch) when V_{DD} is not present.

3 4 B . th

At startup, boot pins are used to select one of three boot options:

- Boot from main flash memory (default)
- Boot from system memory
- Boot from on-chip SRAM

In default condition, boot from main Flash memory is selected. The boot loader is located in the internal boot ROM memory (system memory). It is used to reprogram the Flash memory by using USART0 (PA9 and PA10).

3 5 Power Management

The MCU supports three kinds of power saving modes to achieve even lower power consumption. They are Sleep mode, Deep-sleep mode, and Standby mode. These operating modes reduce the power consumption and allow the application to achieve the best balance between the CPU operating time, speed and power consumption.

■ Sleep mode

In sleep mode, only the clock of CPU core is off. All peripherals continue to operate and any interrupt/event can wake up the system.

■ Deep-sleep mode

In deep-sleep mode, all clocks in the 1.2V domain are off, and all of the high speed crystal oscillator (IRC8M, IRC48M, HXTAL) and PLL are disabled. Only the contents of SRAM and registers are retained. Any interrupt or wakeup event from EXTI lines can wake up the system from the deep-sleep mode including the 16 external lines, the RTC alarm, the LVD output, and USB wakeup. When exiting the deep-sleep mode, the IRC8M is selected as the system clock.

■ Standby mode

In standby mode, the whole 1.2V domain is power off, the LDO is shut down, and all of IRC8M, IRC48M, HXTAL and PLL are disabled. The contents of SRAM and registers (except Backup Registers) are lost. There are four wakeup sources for the standby mode, including the external reset from NRST pin, the RTC, the FWDG reset, and the rising edge on WKUP pin.

3 6 Analog () ADC

- 12-bit SAR ADC's conversion rate is up to 3 MSPS
- 12-bit, 10-bit, 8-bit or 6-bit configurable resolution
- Hardware oversampling ratio adjustable from 2 to 256x improves resolution to 16-bit
- Input voltage range: V_{REF-} to V_{REF+}
- Temperature sensor

Up to two 12-bit 3 MSPS multi-channel ADCs are integrated in the device. It has a total of 18 multiplexed channels: 16 external channels, 1 channel for internal temperature sensor (V_{SENSE}), 1 channel for internal reference voltage (V_{REFINT} , $V_{REFINT} = 1.2V$). The input voltage range is from V_{REF-} to V_{REF+} . An on-chip hardware oversampling scheme improves performance while off-loading the related computational burden from the CPU. An analog watchdog block can be used to detect the channels, which are required to remain within a specific threshold window. A configurable channel management block can be used to perform conversions in single, continuous, scan or discontinuous mode to support more advanced use.

The ADC can be triggered from the events generated by the general level 0 timers (TIMERx, x=1, 2, 3) and the advanced timers (TIMER0 and TIMER7) with internal connection. The

temperature sensor can be used to generate a voltage that varies linearly with temperature. It is internally connected to the ADC_IN16 input channel which is used to convert the sensor output voltage in a digital value.

3 7 **Dg b g D AC**

- 12-bit DAC with independent output channels
- 8-bit or 12-bit mode in conjunction with the DMA controller

The 12-bit buffered DAC is used to generate variable analog outputs. The DAC channels can be triggered by the timer or EXTI with DMA support. In dual DAC channel operation, conversions could be done independently or simultaneously. The maximum output value of the DAC is V_{REF+} .

3 8 **DM**

- 7 channel DMA0 controller and 5 channel DMA1 controller
- Peripherals supported: Timers, ADC, SPIs, I2Cs, USARTs, DAC, I2S

The flexible general-purpose DMA controllers provide a hardware method of transferring data between peripherals and/or memory without intervention from the CPU, thereby freeing up bandwidth for other system functions. Three types of access method are supported: peripheral to memory, memory to peripheral, memory to memory.

Each channel is connected to fixed hardware DMA requests. The priorities of DMA channel requests are determined by software configuration and hardware channel number. Transfer size of source and destination are independent and configurable.

3 9 **Gb -p B**

- Up to 80 fast GPIOs, all mappable on 16 external interrupt lines
- Analog input/output configurable
- Alternate function input/output configurable

There are up to 80 general purpose I/O pins (GPIO) in GD32E103xx, named PA0 ~ PA15, PB0 ~ PB15, PC0 ~ PC15, PD0 ~ PD15 and PE0 ~ PE15 to implement logic input/output functions. Each of the GPIO ports has related control and configuration registers to satisfy the requirements of specific applications. The external interrupts on the GPIO pins of the device have related control and configuration registers in the Interrupt/event controller (EXTI). The GPIO ports are pin-shared with other alternative functions (AFs) to obtain maximum flexibility on the package pins. Each of the GPIO pins can be configured by software as output (push-pull or open-drain), as input (with or without pull-up or pull-down) or as peripheral alternate function. Most of the GPIO pins are shared with digital or analog alternate functions. All GPIOs are high-current capable except for analog inputs.

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- Two 16-bit advanced timer (TIMER0 & TIMER7), ten 16-bit general timers (TIMER1 ~ TIMER4, TIMER8 ~ TIMER13), and two 16-bit basic timer (TIMER5 & TIMER6)
- Up to 4 independent channels of PWM, output compare or input capture for each general timer and external trigger input
- 16-bit, motor control PWM advanced timer with programmable dead-time generation for output match
- Encoder interface controller with two inputs using quadrature decoder
- 24-bit SysTick timer down counter
- 2 watchdog timers (free watchdog timer and window watchdog timer)

The advanced timer (TIMER0 & TIMER7) can be used as a three-phase PWM multiplexed on 6 channels. It has complementary PWM outputs with programmable dead-time generation. It can also be used as a complete general timer. The 4 independent channels can be used for input capture, output compare, PWM generation (edge-aligned or center-aligned counting modes) and single pulse mode output. If configured as a general 16-bit timer, it has the same functions as the TIMERx timer. It can be synchronized with external signals or to interconnect with other general timers together which have the same architecture and features.

The general timer, can be used for a variety of purposes including general time, input signal pulse width measurement or output waveform generation such as a single pulse generation or PWM output, up to 4 independent channels for input capture/output compare. TIMER1 ~ TIMER4 is based on a 16-bit auto-reload up/downcounter and a 16-bit prescaler. TIMER8 ~ TIMER13 is based on a 16-bit auto-reload upcounter and a 16-bit prescaler. The general timer also supports an encoder interface with two inputs using quadrature decoder.

The basic timer, known as TIMER5 & TIMER6, are mainly used for DAC trigger generation. They can also be used as a simple 16-bit time base.

The GD32E103xx have two watchdog peripherals, free watchdog timer and window watchdog timer. They offer a combination of high safety level, flexibility of use and timing accuracy.

The free watchdog timer includes a 12-bit down-counting counter and an 8-bit prescaler. It is clocked from an independent 40 KHz internal RC and as it operates independently of the main clock, it can operate in deep-sleep and standby modes. It can be used either as a watchdog to reset the device when a problem occurs, or as a free-running timer for application timeout management.

The window watchdog timer is based on a 7-bit down counter that can be set as free-running. It can be used as a watchdog to reset the device when a problem occurs. It is clocked from the main clock. It has an early wakeup interrupt capability and the counter can be frozen in debug mode.

The SysTick timer is dedicated for OS, but could also be used as a standard down counter. It features:

- A 24-bit down counter
- Auto reload capability
- Maskable system interrupt generation when the counter reaches 0
- Programmable clock source

3 1 Rtc ()

- 32-bit up-counter with a programmable 20-bit prescaler
- Alarm function
- Interrupt and wake-up event

The real time clock is an independent timer which provides a set of continuously running counters which can be used with suitable software to provide a clock calendar function, and provides an alarm interrupt and an expected interrupt. The RTC features a 32-bit programmable counter for long-term measurement using the compare register to generate an alarm. A 20-bit prescaler is used for the time base clock and is by default configured to generate a time base of 1 second from a clock at 32.768 KHz from external crystal oscillator.

3 2 I2c ()

- Up to two I2C bus interfaces can support both master and slave mode with a frequency up to 1 MHz (Fast mode plus)
- Provide arbitration function, optional PEC (packet error checking) generation and checking
- Supports 7-bit and 10-bit addressing mode and general call addressing mode

The I2C interface is an internal circuit allowing communication with an external I2C interface which is an industry standard two line serial interface used for connection to external hardware. These two serial lines are known as a serial data line (SDA) and a serial clock line (SCL). The I2C module provides several data transfer rates: up to 100 KHz of standard mode, up to 400 KHz of the fast mode and up to 1 MHz of the fast mode plus. The I2C module also has an arbitration detect function to prevent the situation where more than one master attempts to transmit data to the I2C bus at the same time. A CRC-8 calculator is also provided in I2C interface to perform packet error checking for I2C data.

3 3 Sp ()

- Up to three SPI interfaces with a frequency of up to 30 MHz
- Support both master and slave mode
- Hardware CRC calculation and transmit automatic CRC error checking
- Quad-SPI configuration available in master mode (only in SPI0)
- SPI TI mode and NSS pulse mode supported

The SPI interface uses 4 pins, among which are the serial data input and output lines (MISO & MOSI), the clock line (SCK) and the slave select line (NSS). Both SPIs can be served by the DMA controller. The SPI interface may be used for a variety of purposes, including simplex synchronous transfers on two lines with a possible bidirectional data line or reliable communication using CRC checking.

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UART

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- Up to three USARTs and two UARTs with operating frequency up to 7.5Mbits/s
- Supports both asynchronous and clocked synchronous serial communication modes
- IrDA SIR encoder and decoder support
- LIN break generation and detection
- USARTs support ISO 7816-3 compliant smart card interface

The USART (USART0, USART1 and USART2) and UART (UART3 & UART4) are used to translate data between parallel and serial interfaces, provides a flexible full duplex data exchange using synchronous or asynchronous transfer. It is also commonly used for RS-232 standard communication. The USART/UART includes a programmable baud rate generator which is capable of dividing the system clock to produce a dedicated clock for the USART transmitter and receiver. The USART/UART also supports DMA function for high speed data communication except UART4.

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I2S

- Two I2S bus interfaces with sampling frequency from 8 KHz to 192 KHz
- Support either master or slave mode

The Inter-IC sound (I2S) bus provides a standard communication interface for digital audio applications by 3-wire serial lines. GD32E103xx contain two I2S-bus interfaces that can be operated with 16/32 bit resolution in master or slave mode, pin multiplexed with SPI1 and SPI2. The audio sampling frequency from 8 KHz to 192 KHz is supported.

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USB

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- One full-speed USB Interface with frequency up to 12 Mbit/s
- Internal 48 MHz oscillator support crystal-less operation
- Internal main PLL for USB CLK compliantly

The Universal Serial Bus (USB) is a 4-wire bus with 4 bidirectional endpoints. The device controller enables 12 Mbit/s data exchange with integrated transceivers. Transaction formatting is performed by the hardware, including CRC generation and checking. It supports

device modes. The status of a completed USB transfer or error condition is indicated by status registers. An interrupt is also generated if enabled. The required precise 48 MHz clock which can be generated from the internal main PLL (the clock source must use an HXTAL crystal oscillator) or by the internal 48 MHz oscillator in automatic trimming mode that allows crystal-less operation.

3.7 CAN Controller

- Two CAN interface supports the CAN protocols version 2.0A, 2.0B, ISO11891-1:2015 and BOSCH CAN FD specification with communication frequency up to 1 Mbit/s of classic frames and 6 Mbit/s of FD frames
- Internal main PLL for CAN CLK compliantly

Controller area network (CAN) is a method for enabling serial communication in field bus. The CAN protocol has been used extensively in industrial automation and automotive applications. It can receive and transmit standard frames with 11-bit identifiers as well as extended frames with 29-bit identifiers. Each CAN has three mailboxes for transmission and two FIFOs of three message deep for reception. It also provides 28 scalable/configurable identifier filter banks for selecting the incoming messages needed and discarding the others.

3.8 External Memory Controller

- Supported external memory: SRAM, PSRAM, ROM and NOR-Flash
- Up to 16-bit data bus
- Support to interface with Motorola 6800 and Intel 8080 type LCD directly

External memory controller (EXMC) is an abbreviation of external memory controller. It is divided in to several sub-banks for external device support, each sub-bank has its own chip selection signal but at one time, only one bank can be accessed. The EXMC support code execution from external memory. The EXMC also can be configured to interface with the most common LCD module of Motorola 6800 and Intel 8080 series and reduce the system cost and complexity.

3.9 Debug

- Serial wire JTAG debug port (SWJ-DP)

The ARM®SWJ-DP Interface is embedded and is a combined JTAG and serial wire debug port that enables either a serial wire debug or a JTAG probe to be connected to the target.

3.10 Package

- LQFP100 (GD32E103Vx), LQFP64 (GD32E103Rx) and LQFP48 (GD32E103Cx) QFN36



(GD32E103Tx)

- Operation temperature range: -40°C to + 85°C (industrial level)

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The maximum ratings are the limits to which the device can be subjected without permanently damaging the device. Note that the device is not guaranteed to operate properly at the maximum ratings. Exposure to the absolute maximum rating conditions for extended periods may affect device reliability.

4-1. Absolute Maximum Ratings (continued)

Symbol	Parameter	Min	Max	Unit
V_{DD}	External voltage range ⁽²⁾	$V_{SS} - 0.3$	$V_{SS} + 3.6$	V
V_{DDA}	External analog supply voltage	$V_{SSA} - 0.3$	$V_{SSA} + 3.6$	V
V_{BAT}	External battery supply voltage	$V_{SS} - 0.3$	$V_{SS} + 3.6$	V
V_{IN}	Input voltage on 5V tolerant pin ⁽³⁾	$V_{SS} - 0.3$	$V_{DD} + 3.6$	V
	Input voltage on other I/O	$V_{SS} - 0.3$	3.6	V
$ V_{DDX} $	Variations between different V_{DD} power pins		50	mV
$ V_{SSX} - V_{SS} $	Variations between different ground pins		50	mV
I_{IO}	Maximum current for GPIO pins		± 25	mA
T_A	Operating temperature range	-40	+85	°C
P_D	Power dissipation at $T_A = 85^\circ\text{C}$ of LQFP100		813	mW
	Power dissipation at $T_A = 85^\circ\text{C}$ of LQFP64		733	
	Power dissipation at $T_A = 85^\circ\text{C}$ of LQFP48		574	
	Power dissipation at $T_A = 85^\circ\text{C}$ of QFN36		1086	
T_{STG}	Storage temperature range	-55	+150	°C
T_J	Maximum junction temperature		125	°C

- (1) Guaranteed by design, not tested in production.
- (2) All main power and ground pins should be connected to an external power source within the allowable range.
- (3) V_{IN} maximum value cannot exceed 6.5 V.
- (4) It is recommended that V_{DD} and V_{DDA} are powered by the same source. The maximum difference between V_{DD} and V_{DDA} does not exceed 300 mV during power-up and operation.

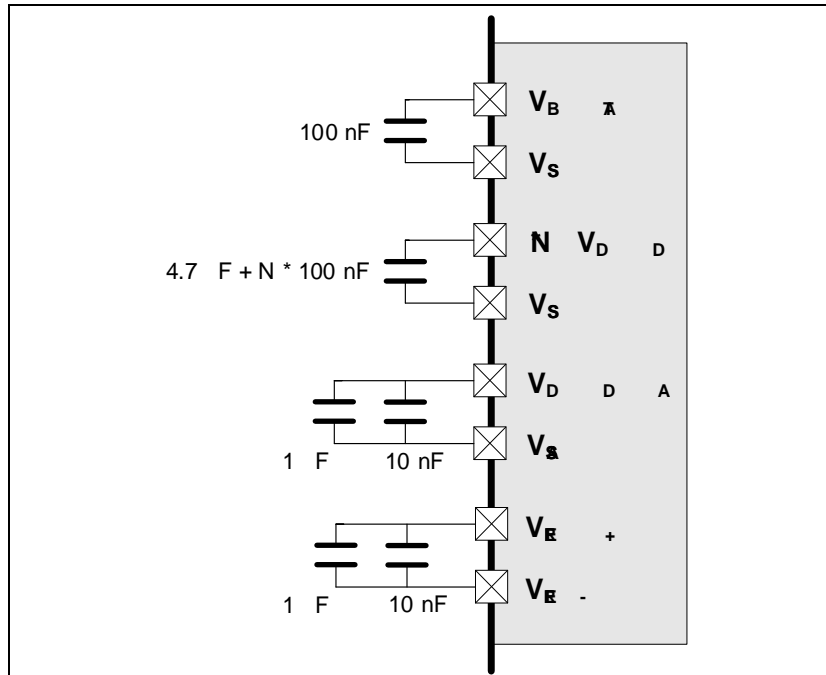
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4-2.D Recommended Operating Conditions

Symbol	Parameter	Min	Typ	Max	Unit
V_{DD}	Supply voltage	1.71	3.3	3.6	V
V_{DDA}	Analog supply voltage ADC not used	1.71	3.3	3.6	V
	Analog supply voltage ADC used	2.4	3.3	3.6	
V_{BAT}	Battery supply voltage	1.71		3.6	V

- (1) Guaranteed by design, not tested in production.

4-2.E Recommended Operating Conditions (continued)



- (1) The V_{REF+} and V_{REF-} pins are only available on no less than 100-pin packages, or else the V_{REF+} and V_{REF-} pins are not available and internally connected to V_{DDA} and V_{SSA} pins.
- (2) All decoupling capacitors need to be as close as possible to the pins on the PCB board.

4-3. ()

Symbol	Description	Unit	Min	Max	Typ
f _{HCLK}	AHB clock frequency			120	MHz
f _{APB1}	APB1 clock frequency			60	MHz
f _{APB2}	APB2 clock frequency			120	MHz

- (1) Guaranteed by design, not tested in production.

4-4. ()

Symbol	Description	Unit	Min	Max	Typ
t _{VDD}	V _{DD} rise time rate		0		s/V
	V _{DD} fall time rate		20		

- (1) Guaranteed by design, not tested in production.

4-5. (2)(3)

Symbol	Description	Unit	Min	Max	Typ
t _{start-up}	Start-up time	Clock source from HXTAL	468		s
		Clock source from IRC8M	86.8		

- (1) Based on characterization, not tested in production.
- (2) After power-up, the start-up time is the time between the rising edge of NRST high and the main function.
- (3) PLL is off.

4-6. (2)

Symbol	Description	Unit	Min	Max	Typ
t _{Sleep}	Wakeup from Sleep mode		4.3		s
t _{Deep-sleep}	Wakeup from Deep-sleep mode LDO On		18.0		
	Wakeup from Deep-sleep mode LDO in low power		18.0		

Symbol	Parameter	Value	Unit
	mode		
$t_{Standby}$	Wakeup from Standby mode	82.0	

- (1) Based on characterization, not tested in production.
- (2) The wakeup time is measured from the wakeup event to the point at which the application code reads the first instruction under the below conditions: $V_{DD} = V_{DDA} = 3.3\text{ V}$, IRC8M = System clock = 8 MHz.

4. Power consumption

The power measurements specified in the tables represent that code with data executing from on-chip Flash with the following specifications.

Table 4-7. Supply current (Run mode)

Symbol	Parameter	Conditions	Value	Unit
$I_{DD}+I_{DDA}$	Supply current (Run mode)	$V_{DD} = V_{DDA} = 3.3\text{ V}$, HXTAL = 25 MHz, System clock=120 MHz, All peripherals enabled	28.1	mA
		$V_{DD} = V_{DDA} = 3.3\text{ V}$, HXTAL = 25 MHz, System clock = 120 MHz, All peripherals disabled	16.0	mA
		$V_{DD} = V_{DDA} = 3.3\text{ V}$, HXTAL = 25 MHz, System clock = 108 MHz, All peripherals enabled	24.6	mA
		$V_{DD} = V_{DDA} = 3.3\text{ V}$, HXTAL = 25 MHz, System clock = 108 MHz, All peripherals disabled	14.7	mA
		$V_{DD} = V_{DDA} = 3.3\text{ V}$, HXTAL = 25 MHz, System clock = 96 MHz, All peripherals enabled	22.3	mA
		$V_{DD} = V_{DDA} = 3.3\text{ V}$, HXTAL = 25 MHz, System clock = 96 MHz, All peripherals disabled	13.6	mA
		$V_{DD} = V_{DDA} = 3.3\text{ V}$, HXTAL = 25 MHz, System clock = 72 MHz, All peripherals enabled	17.2	mA
		$V_{DD} = V_{DDA} = 3.3\text{ V}$, HXTAL = 25 MHz, System clock = 72 MHz, All peripherals disabled	10.8	mA
		$V_{DD} = V_{DDA} = 3.3\text{ V}$, HXTAL = 25 MHz, System clock = 48 MHz, All peripherals enabled	12.3	mA
		$V_{DD} = V_{DDA} = 3.3\text{ V}$, HXTAL = 25 MHz, System clock = 48 MHz, All peripherals disabled	8.1	mA

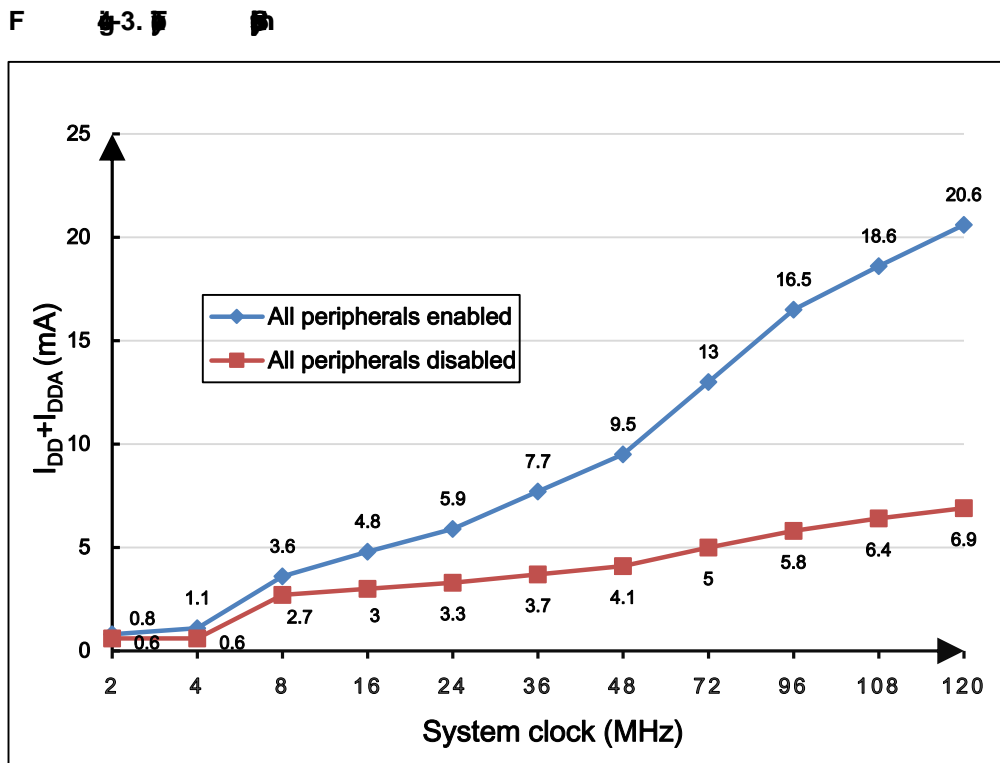
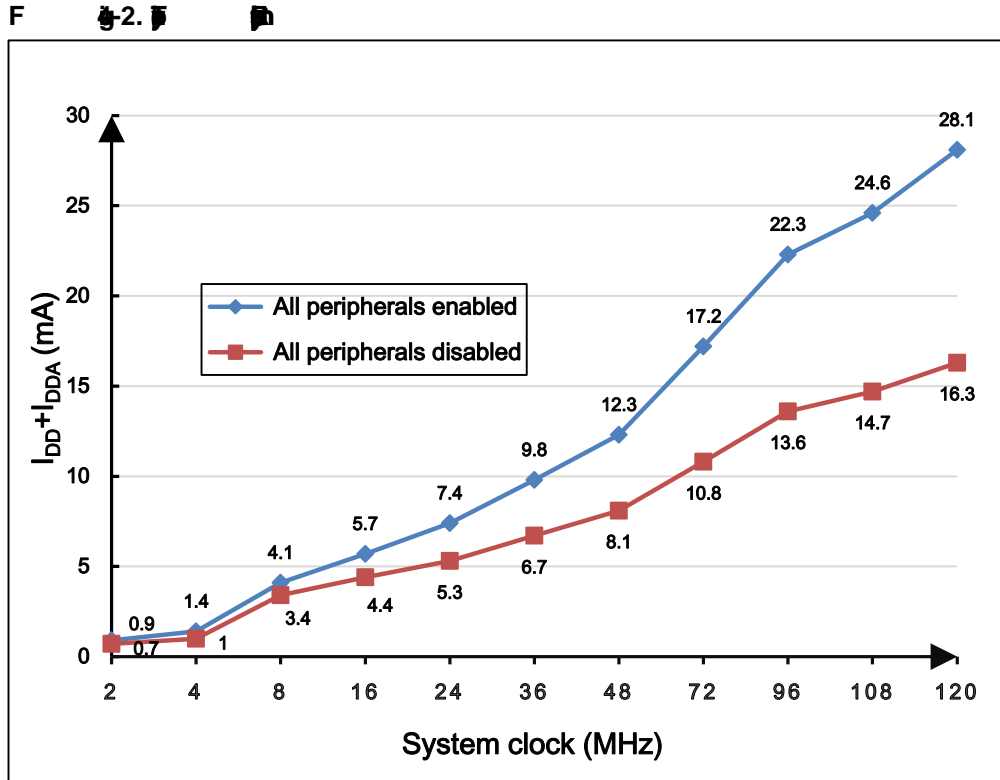
Symbol	Unit	Condition	Min	Typ	Max	Unit
		V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System clock = 36 MHz, All peripherals enabled		9.8		mA
		V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System clock = 36 MHz, All peripherals disabled		6.7		mA
		V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System clock = 24 MHz, All peripherals enabled		7.4		mA
		V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System clock = 24 MHz, All peripherals disabled		5.3		mA
		V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System clock = 16 MHz, All peripherals enabled		5.7		mA
		V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System clock = 16 MHz, All peripherals disabled		4.4		mA
		V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System clock = 8 MHz, All peripherals enabled		4.1		mA
		V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System clock = 8 MHz, All peripherals disabled		3.4		mA
		V _{DD} = V _{DDA} = 3.3 V, HXTAL = 4 MHz, System clock = 4 MHz, All peripherals enabled		1.3		mA
		V _{DD} = V _{DDA} = 3.3 V, HXTAL = 4 MHz, System clock = 4 MHz, All peripherals disabled		1.0		mA
		V _{DD} = V _{DDA} = 3.3 V, HXTAL = 2 MHz, System clock = 2 MHz, All peripherals enabled		0.9		mA
		V _{DD} = V _{DDA} = 3.3 V, HXTAL = 2 MHz, System Clock = 2 MHz, All peripherals disabled		0.7		mA
		Supply current (Sleep mode)		V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System Clock = 120 MHz, CPU clock off, All peripherals enabled		20.5
V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System Clock = 120 MHz, CPU clock off, All peripherals disabled				6.9		mA

Mode	Condition	Current (mA)	Current (mA)	Current (mA)
	V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System Clock = 108 MHz, CPU clock off, All peripherals enabled		18.6	mA
	V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System Clock = 108 MHz, CPU clock off, All peripherals disabled		6.4	mA
	V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System Clock = 96 MHz, CPU clock off, All peripherals enabled		16.5	mA
	V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System Clock = 96 MHz, CPU clock off, All peripherals disabled		5.8	mA
	V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System Clock = 72 MHz, CPU clock off, All peripherals enabled		13	mA
	V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System Clock = 72 MHz, CPU clock off, All peripherals disabled		5	mA
	V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System Clock = 48 MHz, CPU clock off, All peripherals enabled		9.5	mA
	V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System Clock = 48 MHz, CPU clock off, All peripherals disabled		4.1	mA
	V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System Clock = 36 MHz, CPU clock off, All peripherals enabled		7.7	mA
	V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System Clock = 36 MHz, CPU clock off, All peripherals disabled		3.7	mA
	V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System Clock = 24 MHz, CPU clock off, All peripherals enabled		5.9	mA
	V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System Clock = 24 MHz, CPU clock off, All peripherals disabled		3.3	mA
	V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System Clock = 16 MHz, CPU clock off, All peripherals enabled		4.8	mA
	V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System Clock = 16 MHz, CPU clock off, All peripherals disabled		3	mA

Mode	Condition	Current	Max	Typ	Min	Unit
I _{DD}	Supply current (Normal mode)	V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System Clock = 8 MHz, CPU clock on, All peripherals enabled		3.6		mA
		V _{DD} = V _{DDA} = 3.3 V, HXTAL = 25 MHz, System Clock = 8 MHz, CPU clock off, All peripherals disabled		2.7		mA
		V _{DD} = V _{DDA} = 3.3 V, HXTAL = 4 MHz, System Clock = 4 MHz, CPU clock on, All peripherals enabled		1.1		mA
		V _{DD} = V _{DDA} = 3.3 V, HXTAL = 4 MHz, System Clock = 4 MHz, CPU clock off, All peripherals disabled		0.6		mA
		V _{DD} = V _{DDA} = 3.3 V, HXTAL = 2 MHz, System Clock = 2 MHz, CPU clock on, All peripherals enabled		0.8		mA
		V _{DD} = V _{DDA} = 3.3 V, HXTAL = 2 MHz, System Clock = 2 MHz, CPU clock off, All peripherals disabled		0.6		mA
	Supply current (Deep-Sleep mode)	V _{DD} = V _{DDA} = 3.3 V, LDO in run mode, IRC40K off, RTC off, All GPIOs analog mode		41.8	550	A
		V _{DD} = V _{DDA} = 3.3 V, LDO in low power mode, IRC40K off, RTC off, All GPIOs analog mode		31.8	550	A
		V _{DD} = V _{DDA} = 3.3 V, LXTAL off, IRC40K on, RTC on		2.1	11	A
	Supply current (Standby mode)	V _{DD} = V _{DDA} = 3.3 V, LXTAL off, IRC40K on, RTC off		2.0	11	□□
		V _{DD} = V _{DDA} = 3.3 V, LXTAL off, IRC40K off, RTC off		1.5	11	□□
		V _{DD} off, V _{DDA} off, V _{BAT} = 3.6 V, LXTAL on with external crystal, RTC on, LXTAL High driving		1.6		A
I _{BAT}	Battery supply current (Backup mode)	V _{DD} off, V _{DDA} off, V _{BAT} = 3.3 V, LXTAL on with external crystal, RTC on, LXTAL High driving		1.4		A□
		V _{DD} off, V _{DDA} off, V _{BAT} = 2.5 V, LXTAL on with external crystal, RTC on, LXTAL High driving		1.3		A□
		V _{DD} off, V _{DDA} off, V _{BAT} = 1.71 V, LXTAL on with external crystal, RTC on, LXTAL High driving		1.2		□□
		V _{DD} off, V _{DDA} off, V _{BAT} = 1.71 V, LXTAL on with external crystal, RTC on, LXTAL High driving		1.2		□□

Mode	Supply Voltage	Operating Current	Supply Current	Operating Voltage	Operating Current	Supply Current
	V _{DD} off, V _{DDA} off, V _{BAT} = 3.6 V, LXTAL on with external crystal, RTC on, LXTAL Medium High driving			1.3		□□
	V _{DD} off, V _{DDA} off, V _{BAT} = 3.3 V, LXTAL on with external crystal, RTC on, LXTAL Medium High driving			1.1		A□
	V _{DD} off, V _{DDA} off, V _{BAT} = 2.5 V, LXTAL on with external crystal, RTC on, LXTAL Medium High driving			1.0		□□
	V _{DD} off, V _{DDA} off, V _{BAT} = 1.71 V, LXTAL on with external crystal, RTC on, LXTAL Medium High driving			0.9		□□
	V _{DD} off, V _{DDA} off, V _{BAT} = 3.6 V, LXTAL on with external crystal, RTC on, LXTAL Medium Low driving			1.0		A□
	V _{DD} off, V _{DDA} off, V _{BAT} = 3.3 V, LXTAL on with external crystal, RTC on, LXTAL Medium Low driving			0.9		□□
	V _{DD} off, V _{DDA} off, V _{BAT} = 2.5 V, LXTAL on with external crystal, RTC on, LXTAL Medium Low driving			0.7		□□
	V _{DD} off, V _{DDA} off, V _{BAT} = 1.71 V, LXTAL on with external crystal, RTC on, LXTAL Medium Low driving			0.6		A□
	V _{DD} off, V _{DDA} off, V _{BAT} = 3.6 V, LXTAL on with external crystal, RTC on, LXTAL Low driving			0.9		□□
	V _{DD} off, V _{DDA} off, V _{BAT} = 3.3 V, LXTAL on with external crystal, RTC on, LXTAL Low driving			0.8		□□
	V _{DD} off, V _{DDA} off, V _{BAT} = 2.5 V, LXTAL on with external crystal, RTC on, LXTAL Low driving			0.6		A□
	V _{DD} off, V _{DDA} off, V _{BAT} = 1.71 V, LXTAL on with external crystal, RTC on, LXTAL Low driving			0.5		A

- (1) Based on characterization, not tested in production.
- (2) Unless otherwise specified, all values given for T_A = 25 °C and test result is mean value.
- (3) When System Clock is less than 4 MHz, an external source is used, and the HXTAL bypass function is needed, no PLL.
- (4) When System Clock is greater than 8 MHz, a crystal 25 MHz is used, and the HXTAL bypass function is closed, using PLL.
- (5) When analog peripheral blocks such as ADCs, DACs, HXTAL, LXTAL, IRC8M, or IRC40K are ON, an additional power consumption should be considered.



4-8

Port	Peripheral	Current (mA)	Temperature (°C)
APB1	DAC ⁽²⁾	0.44	

	() 4	5	°C ()	b
	PMU		0.18	
	BKPI		0.38	
	CAN1		0.3	
	CAN0		0.32	
	I2C1		0.77	
	I2C0		0.77	
	UART4		0.78	
	UART3		0.78	
	USART2		0.78	
	USART1		0.78	
	SPI2		0.72	
	SPI1		0.78	
	WWDGT		0.03	
	TIMER13		0.32	
	TIMER12		0.3	
	TIMER11		0.31	
	TIMER6		0.05	
	TIMER5		0.04	
	TIMER4		0.38	
	TIMER3		0.37	
	TIMER2		0.36	
	TIMER1		0.37	
ADDAPB1	CTC		0.68	
APB2	TIMER10		0.56	
	TIMER9		0.58	
	TIMER8		0.6	
	USART0		0.52	
	TIMER7		0.87	
	SPI0		0.09	
	TIMER0		0.65	
	ADC1 ⁽³⁾		1.36	
	ADC0 ⁽³⁾		1.35	
	GPIOE		0.18	
	GIPOD		0.19	
	GPIOC		0.2	
	GPIOB		0.18	
	GPIOA		0.19	
GPIOF		0.04		
AHB	USBFS		1.48	
	EXMC		0.29	
	CRC		0.03	

	() 4	5	°C ()	td
	DMA1		0.31	
	DMA0		0.39	

- (1) Based on characterization, not tested in production.
- (2) DEN0 and DEN1 bits in the DAC_CTL register are set to 1, and the converted value set to 0x800.
- (3) System clock = $f_{HCLK} = 72 \text{ MHz}$, $f_{APB1} = f_{HCLK}/2$, $f_{APB2} = f_{HCLK}$, $f_{ADCCLK} = f_{APB2}/2$, ADCON bit is set to 1.
- (4) If there is no other description, then HXTAL = 25 MHz, system clock = $f_{HCLK} = 120 \text{ MHz}$, $f_{APB1} = f_{HCLK}/2$, $f_{APB2} = f_{HCLK}$.

4 . 4 b .

EMS (electromagnetic susceptibility) includes ESD (Electrostatic discharge, positive and negative) and FTB (Burst of Fast Transient voltage, positive and negative) testing result is given in the [Table 4-9. EMS characteristics](#), based on the EMS levels and classes compliant with IEC 61000 series standard.

Table 4-9. EMS characteristics ()

Symbol	Description	Test Conditions	Level
V_{ESD}	Voltage applied to all device pins to induce a functional disturbance	$V_{DD} = 3.3 \text{ V}$, $T_A = 25 \text{ °C}$, LQFP100, $f_{HCLK} = 120 \text{ MHz}$ conforms to IEC 61000-4-2	3A
V_{FTB}	Fast transient voltage burst applied to induce a functional disturbance through 100 pF on V_{DD} and V_{SS} pins	$V_{DD} = 3.3 \text{ V}$, $T_A = 25 \text{ °C}$, LQFP100, $f_{HCLK} = 120 \text{ MHz}$ conforms to IEC 61000-4-4	4A

- (1) Based on characterization, not tested in production.

4 . 5

Table 4-0 .

Symbol	Description	Test Conditions	M	F	M	td
$V_{LVD}^{(1)}$	Low voltage Detector Threshold	LVDT<2:0> = 000(rising edge)		2.07		V
		LVDT<2:0> = 000(falling edge)		1.97		
		LVDT<2:0> = 001(rising edge)		2.2		
		LVDT<2:0> = 001(falling edge)		2.1		
		LVDT<2:0> = 010(rising edge)		2.34		
		LVDT<2:0> = 010(falling edge)		2.24		
		LVDT<2:0> = 011(rising edge)		2.47		
		LVDT<2:0> = 011(falling edge)		2.37		
		LVDT<2:0> = 100(rising edge)		2.61		

Symbol	Parameter	Condition	Min	Typ	Max	Unit
		LVDT<2:0> = 100(falling edge)		2.51		
		LVDT<2:0> = 101(rising edge)		2.74		
		LVDT<2:0> = 101(falling edge)		2.64		
		LVDT<2:0> = 110(rising edge)		2.88		
		LVDT<2:0> = 110(falling edge)		2.78		
		LVDT<2:0> = 111(rising edge)		3.01		
		LVDT<2:0> = 111(falling edge)		2.91		
$V_{LVDhyst}^{(2)}$	LVD hysteresis			100		mV
$V_{POR}^{(1)}$	Power on reset threshold			1.67		V
$V_{PDR}^{(1)}$	Power down reset threshold			1.62		V
$V_{PDRhyst}^{(2)}$	PDR hysteresis			40		mV
$t_{RSTTEMPO}^{(2)}$	Reset temporization			2		ms

(1) Based on characterization, not tested in production.

(2) Guaranteed by design, not tested in production.

4. ESD

The device is strained in order to determine its performance in terms of electrical sensitivity. Electrostatic discharges (ESD) are applied directly to the pins of the sample. Static latch-up (LU) test is based on the two measurement methods.

4-1. ESD ()

Symbol	Parameter	Condition	Min	Typ	Max	Unit
$V_{ESD(HBM)}$	Electrostatic discharge voltage (human body model)	$T_A = 25\text{ }^{\circ}\text{C}$; JESD22-A114			5000	V
$V_{ESD(CDM)}$	Electrostatic discharge voltage (charge device model)	$T_A = 25\text{ }^{\circ}\text{C}$; JESD22-C101			800	V

(1) Based on characterization, not tested in production.

4-2. I-test

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
LU	I-test	$T_A = 25\text{ }^\circ\text{C}$; JESD78			± 200	mA
	$V_{\text{supply over voltage}}$				5.4	V

(1) Based on characterization, not tested in production.

4.3. HXTAL
4-3. HXTAL Parameters

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$f_{\text{HXTAL}}^{(1)}$	Crystal or ceramic frequency	$1.71 V_{\text{DD}}$ ~ 3.6 V	4	8	32	MHz
$R_F^{(2)}$	Feedback resistor	$V_{\text{DD}} = 3.3\text{ V}$		400		k
$C_{\text{HXTAL}}^{(2)(3)}$	Recommended matching capacitance on OSCIN and OSCOUT			20	30	pF
$D_{\text{ucy}}(\text{HXTAL})^{(2)}$	Crystal or ceramic duty cycle		30	50	70	%
$g_m^{(2)}$	Oscillator transconductance	Startup		25		mA/V
$I_{\text{DD}}(\text{HXTAL})^{(1)}$	Crystal or ceramic operating current	$V_{\text{DD}} = 3.3\text{ V}$, $T_A = 25\text{ }^\circ\text{C}$		1.1		mA
$t_{\text{SUHXTAL}}^{(1)}$	Crystal or ceramic startup time	$V_{\text{DD}} = 3.3\text{ V}$, $T_A = 25\text{ }^\circ\text{C}$		1.8		μs

(1) Based on characterization, not tested in production.

(2) Guaranteed by design, not tested in production.

(3) $C_{\text{HXTAL1}} = C_{\text{HXTAL2}} = 2 * (C_{\text{LOAD}} - C_s)$, For C_{HXTAL1} and C_{HXTAL2} , it is recommended matching capacitance on OSCIN and OSCOUT. For C_{LOAD} , it is crystal/ceramic load capacitance, provided by the crystal or ceramic manufacturer. For C_s , it is PCB and MCU pin stray capacitance.

4-4. HXTAL External Clock

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$f_{\text{HXTAL_ext}}^{(1)}$	External clock source or oscillator frequency	$V_{\text{DD}} = 3.3\text{ V}$	1		50	MHz
$V_{\text{HXTALH}}^{(2)}$	OSCIN input pin high level voltage	$V_{\text{DD}} = 3.3\text{ V}$	$0.7 V_{\text{DD}}$		V_{DD}	V
$V_{\text{HXTALL}}^{(2)}$	OSCIN input pin low level voltage		V_{SS}		$0.3 V_{\text{DD}}$	V
$t_{\text{H/L}}(\text{HXTAL})^{(2)}$	OSCIN high or low time		5			ns
$t_{\text{R/F}}(\text{HXTAL})^{(2)}$	OSCIN rise or fall time				10	ns
$C_{\text{IN}}^{(2)}$	OSCIN input capacitance			5		pF
$D_{\text{ucy}}(\text{HXTAL})^{(2)}$	Duty cycle		40		60	%

(1) Based on characterization, not tested in production.

(2) Guaranteed by design, not tested in production.

4-5 .
b

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$f_{LXTAL}^{(1)}$	Crystal or ceramic frequency	$V_{DD} = 3.3\text{ V}$		32.768		kHz
$C_{LXTAL}^{(2)(3)}$	Recommended matching capacitance on OSC32IN and OSC32OUT			10		pF
$D_{ucy(LXTAL)}^{(2)}$	Crystal or ceramic duty cycle		30		70	%
$g_m^{(2)}$	Oscillator transconductance	Lower driving capability		4		A/V
		Medium low driving capability		6		
		Medium high driving capability		12		
		Higher driving capability		18		
$I_{DDLXTAL}^{(1)}$	Crystal or ceramic operating current	Lower driving capability		0.7		A
		Medium low driving capability		0.8		
		Medium high driving capability		1.1		
		Higher driving capability		1.4		
$t_{SULXTAL}^{(1)(4)}$	Crystal or ceramic startup time			1.8		s

(1) Based on characterization, not tested in production.

(2) Guaranteed by design, not tested in production.

(3) $C_{LXTAL1} = C_{LXTAL2} = 2 * (C_{LOAD} - C_S)$, For C_{LXTAL1} and C_{LXTAL2} , it is recommended matching capacitance on OSC32IN and OSC32OUT. For C_{LOAD} , it is crystal/ceramic load capacitance, provided by the crystal or ceramic manufacturer. For C_S , it is PCB and MCU pin stray capacitance.

(4) $t_{SULXTAL}$ is the startup time measured from the moment it is enabled (by software) to the 32.768 kHz oscillator stabilization flags is SET. This value varies significantly with the crystal manufacturer.

4-6 .

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$f_{LXTAL_ext}^{(1)}$	External clock source or oscillator frequency	$V_{DD} = 3.3\text{ V}$		32.768	1000	kHz
$V_{LXTALH}^{(2)}$	OSC32IN input pin high level voltage		$0.7 V_{DD}$		V_{DD}	V
$V_{LXTALL}^{(2)}$	OSC32IN input pin low level voltage		V_{SS}		$0.3 V_{DD}$	
$t_{H/L(LXTAL)}^{(2)}$	OSC32IN high or low time		450			ns
$t_{R/F(LXTAL)}^{(2)}$	OSC32IN rise or fall time				50	
$C_{IN}^{(2)}$	OSC32IN input capacitance			5		pF
$D_{ucy(LXTAL)}^{(2)}$	Duty cycle		30	50	70	%

(1) Based on characterization, not tested in production.

(2) Guaranteed by design, not tested in production.

M	b
	MH z
+2.5	%
+1.8	%
+1.0	%
	%
55	%
	A
	s

M	b
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4-9 . H B 48 M

Symbol	Parameter	Conditions	M	P	M	U
f_{IRC48M}	High Speed Internal Oscillator (IRC48M) frequency	$V_{DD} = V_{DDA} = 3.3 V$		48		MHz
ACC_{IRC48M}	IRC48M oscillator Frequency accuracy, Factory-trimmed	$V_{DD} = V_{DDA} = 3.3 V$, $T_A = -40\text{ }^{\circ}\text{C} \sim +85\text{ }^{\circ}\text{C}$ (1)	-4.0		5.0	%
		$V_{DD} = V_{DDA} = 3.3 V$, $T_A = 0\text{ }^{\circ}\text{C} \sim +85\text{ }^{\circ}\text{C}$ (1)	-3.0		3.0	%
		$V_{DD} = V_{DDA} = 3.3 V$, $T_A = 25\text{ }^{\circ}\text{C}$	-2.0		2.0	%
	IRC48M oscillator Frequency accuracy, User trimming step ⁽¹⁾			0.1		%
$Ducy_{IRC48M}$ (2)	IRC48M oscillator duty cycle	$V_{DD} = V_{DDA} = 3.3 V$	45	50	55	%
$I_{DDIRC48M}$ (1)	IRC48M oscillator operating current	$V_{DD} = V_{DDA} = 3.3 V$, $f_{IRC48M} = 48\text{ MHz}$		270		A
$t_{SUIRC48M}$ (1)	IRC48M oscillator startup time	$V_{DD} = V_{DDA} = 3.3 V$, $f_{IRC48M} = 48\text{ MHz}$		2.5		s

(1) Based on characterization, not tested in production.

(2) Guaranteed by design, not tested in production.

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4-2 . B 0

Symbol	Parameter	Conditions	M	P	M	U
f_{PLLIN} (1)	PLL input clock frequency		1	8	25	MHz
f_{PLLOUT}	PLL output clock frequency		16		120	MHz
f_{VCO}	VCO output frequency		32		240	MHz
t_{LOCK} (2)	PLL lock time				300	s
I_{DDA} (1)	Current consumption on V_{DDA}	VCO freq = 240 MHz		350		A
$Jitter_{PLL}$ (1)(3)	Cycle to cycle Jitter rms	System clock		46		ps
	Cycle to cycle Jitter peak to peak			463		

(1) Based on characterization, not tested in production.

(2) Guaranteed by design, not tested in production.

(3) Value given with main PLL running.

4-2 . B 1 b

Symbol	Parameter	Conditions	M	P	M	U
f_{PLLIN} (1)	PLL input clock frequency		1	8	25	MHz
f_{PLLOUT}	PLL output clock frequency		16		120	MHz
f_{VCO}	VCO output frequency		32		240	MHz

$t_{LOCK}^{(2)}$	PLL lock time			300	s
$I_{DDA}^{(1)}$	Current consumption on V_{DDA}	VCO freq = 240 MHz		320	A
$Jitter_{PLL}^{(1)(3)}$	Cycle to cycle Jitter rms	System clock		46	ps
	Cycle to cycle Jitter peak to peak			463	

- (1) Based on characterization, not tested in production.
(2) Guaranteed by design, not tested in production.
(3) Value given with main PLL running

4. Memory

4-2. Flash

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$PE_{CYC}^{(1)}$	Number of guaranteed program /erase cycles before failure(Endurance)	$T_A = -40\text{ }^{\circ}\text{C} \sim +85\text{ }^{\circ}\text{C}$	100			kcycles
$t_{RET}^{(1)}$	Data retention time	10k cycles at $T_A = 85\text{ }^{\circ}\text{C}$	10			years
$t_{PROG}^{(2)}$	Word ⁽³⁾ programming time	$T_A = -40\text{ }^{\circ}\text{C} \sim +85\text{ }^{\circ}\text{C}$	37		44	
$t_{ERASE}^{(2)}$	Page erase time	$T_A = -40\text{ }^{\circ}\text{C} \sim +85\text{ }^{\circ}\text{C}$	3.2		4	ms
$t_{MERASE}^{(2)}$	Mass erase time	$T_A = -40\text{ }^{\circ}\text{C} \sim +85\text{ }^{\circ}\text{C}$	8		10	ms

- (1) Based on characterization, not tested in production.
(2) Guaranteed by design, not tested in production.
(3) Word is 32 bits or 64 bits depend on PGW bit in FMC_WS register.

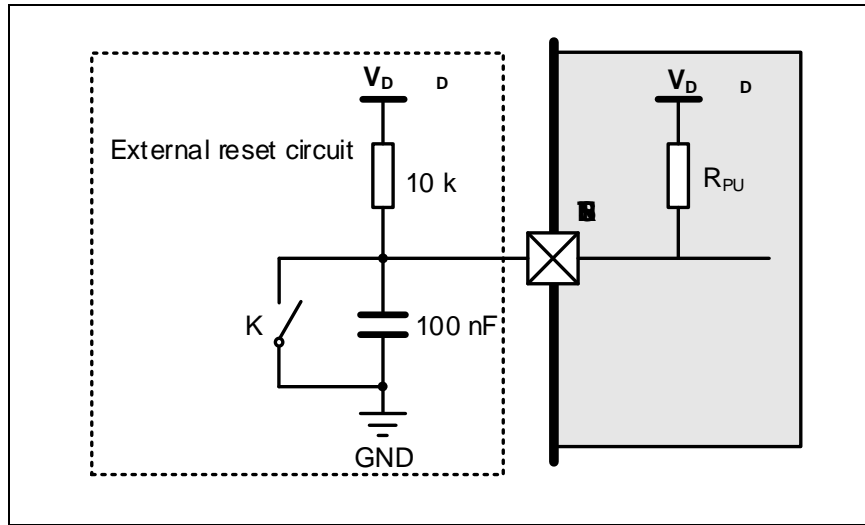
4. I/O

4-2. NRST

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{IL(NRST)}^{(1)}$	NRST Input low level voltage	1. $V_{DD} = V_{DDA}$ 3.6 V	-0.5		0.3 V_{DD}	V
$V_{IH(NRST)}^{(1)}$	NRST Input high level voltage		0.7 V_{DD}		$V_{DD} + 0.45$	
$V_{hyst}^{(1)}$	Schmidt trigger Voltage hysteresis				460	mV
$R_{pu}^{(2)}$	Pull-up equivalent resistor			40		k

- (1) Based on characterization, not tested in production.
(2) Guaranteed by design, not tested in production.

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4-2 4 (3)

Symbol	Description	Condition	V _{DD}	V _{OH}	V _{OL}	Unit
V _{IL}	Standard IO Low level input voltage	1. V _{DD} = V _{DDA}	3.6 V		0.3 V _{DD}	V
	5V-tolerant IO Low level input voltage	1. V _{DD} = V _{DDA}	3.6 V		0.3 V _{DD}	V
V _{IH}	Standard IO High level input voltage	1. V _{DD} = V _{DDA}	3.6 V	0.7 V _{DD}		V
	5V-tolerant IO High level input voltage	1. V _{DD} = V _{DDA}	3.6 V	0.7 V _{DD}		V
V _{OL}	Low level output voltage (I _{IO} = +8 mA)	V _{DD} = 1.8 V			0.32	V
		V _{DD} = 2.5 V			0.24	
		V _{DD} = 3.3 V			0.11	
		V _{DD} = 3.6 V			0.11	
V _{OL}	Low level output voltage (I _{IO} = +20 mA)	V _{DD} = 1.8 V			0.53	V
		V _{DD} = 2.5 V			0.60	
		V _{DD} = 3.3 V			0.28	
		V _{DD} = 3.6 V			0.27	
V _{OH}	High level output voltage (I _{IO} = +8 mA)	V _{DD} = 1.8 V		1.49		V
		V _{DD} = 2.5 V		2.27		
		V _{DD} = 3.3 V		3.14		
		V _{DD} = 3.6 V		3.45		
V _{OH}	High level output voltage (I _{IO} = +20 mA)	V _{DD} = 1.8 V		1.25		V
		V _{DD} = 2.5 V		1.89		
		V _{DD} = 3.3 V		2.91		

Symbol	Description	Unit	Min	Typ	Max	Notes
		$V_{DD} = 3.6\text{ V}$	3.23			
$R_{PU}^{(2)}$	Internal pull-up resistor			40		
$R_{PD}^{(2)}$	Internal pull-down resistor			40		

- (1) Based on characterization, not tested in production.
- (2) Guaranteed by design, not tested in production.
- (3) All pins except PC13 / PC14 / PC15. Since PC13 to PC15 are supplied through the Power Switch, which can only be obtained by a small current, the speed of GPIOs PC13 to PC15 should not exceed 2 MHz when they are in output mode(maximum load: 30 pF).

4-2. I/O port AC characteristics

GPIOx_CTL->MDy[1:0]	Description	Unit	Min	Max	Notes
GPIOx_CTL->MDy[1:0] = 10 (IO_Speed = 2 MHz)	Maximum frequency ⁽⁴⁾	$V_{DD} = 3.6\text{ V}, C_L = 10\text{ pF}$	9		MHz
		$V_{DD} = 3.6\text{ V}, C_L = 30\text{ pF}$	6		
		$V_{DD} = 3.6\text{ V}, C_L = 50\text{ pF}$	4		
GPIOx_CTL->MDy[1:0] = 01 (IO_Speed = 10 MHz)	Maximum frequency ⁽⁴⁾	$V_{DD} = 3.6\text{ V}, C_L = 10\text{ pF}$	50		MHz
		$V_{DD} = 3.6\text{ V}, C_L = 30\text{ pF}$	25		
		$V_{DD} = 3.6\text{ V}, C_L = 50\text{ pF}$	15		
GPIOx_CTL->MDy[1:0] = 11 (IO_Speed = 50 MHz)	Maximum frequency ⁽⁴⁾	$V_{DD} = 3.6\text{ V}, C_L = 10\text{ pF}$	60		MHz
		$V_{DD} = 3.6\text{ V}, C_L = 30\text{ pF}$	30		
		$V_{DD} = 3.6\text{ V}, C_L = 50\text{ pF}$	20		
GPIOx_CTL->MDy[1:0] = 11 and GPIOx_SPDy = 1 (IO_Speed = MAX)	Maximum frequency ⁽⁴⁾	$V_{DD} = 3.6\text{ V}, C_L = 10\text{ pF}$	70		MHz
		$V_{DD} = 3.6\text{ V}, C_L = 30\text{ pF}$	50		
		$V_{DD} = 3.6\text{ V}, C_L = 50\text{ pF}$	30		

- (1) Based on characterization, not tested in production.
- (2) Unless otherwise specified, all test results given for $T_A = 25^\circ\text{C}$.
- (3) The I/O speed is configured using the GPIOx_CTL -> MDy[1:0] bits. Refer to the GD32E103xx user manual which is selected to set the GPIO port output speed.
- (4) The maximum frequency is defined in [Figure 4-5. I/O port AC characteristics definition](#).

Figure 4-5. I/O port AC characteristics definition

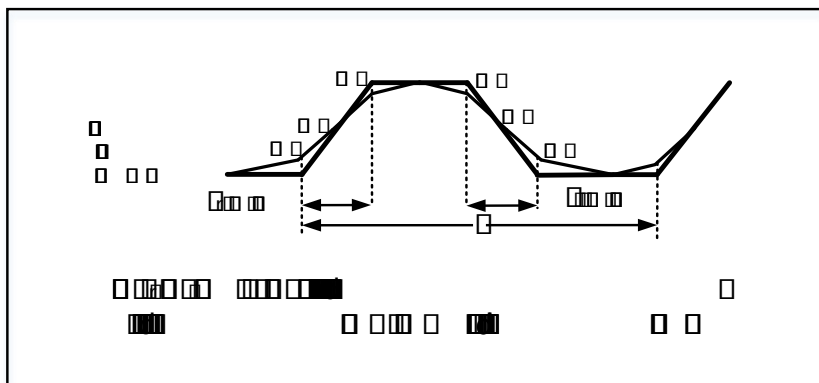


Figure 4-5. I/O port AC characteristics definition

4. 2. 6

4-2.6

Symbol	Description	Min	Typ	Max	Unit	
$V_{DDA}^{(1)}$	Operating voltage	2.4	3.3	3.6	V	
$V_{IN}^{(1)}$	ADC input voltage range	0		V_{REF+}	V	
$f_{ADC}^{(1)}$	ADC clock	0.1		42	MHz	
$f_s^{(1)}$	Sampling rate	12-bit	0.007	3	MSPS	
		10-bit	0.008	3.5		
		8-bit	0.01	4.2		
		6-bit	0.011	5.25		
$V_{AIN}^{(1)}$	Analog input voltage	16 external; 2 internal		0	V_{DDA}	V
$V_{REF+}^{(2)}$	Positive Reference Voltage	1.8		V_{DDA}	V	
$V_{REF-}^{(2)}$	Negative Reference Voltage		V_{SSA}		V	
$R_{AIN}^{(2)}$	External input impedance	See Equation 1			24	
$R_{ADC}^{(2)}$	Input sampling switch resistance				0.2	
$C_{ADC}^{(2)}$	Input sampling capacitance	No pin/pad capacitance included			5.5	pF
$t_{CAL}^{(2)}$	Calibration time	$f_{ADC} = 42$ MHz		3.12		
$t_s^{(2)}$	Sampling time	$f_{ADC} = 42$ MHz		0.036	5.7	
$t_{CONV}^{(2)}$	Total conversion time(including sampling time)	12-bit		14	$1/f_{ADC}$	
		10-bit		12		
		8-bit		10		
		6-bit		8		
$t_{SU}^{(2)}$	Startup time			1	s	

(1) Based on characterization, not tested in production.

(2) Guaranteed by design, not tested in production.

Equation 1: R_{AIN} max formula & _____ &

The formula above (Equation 1) is used to determine the maximum external impedance allowed for an error below 1/4 of LSB. Here $N = 12$ (from 12-bit resolution).

4-2.7 RC

T_s (μs)	t_s (μs)	R_m (kΩ)
1.5	0.04	0.47
7.5	0.18	3.15
13.5	0.32	5.82
28.5	0.68	12.55
41.5	0.99	18.35
55.5	1.32	24.55
71.5	1.70	NA

T_s (ns)	t_s (ns)	R_m (kΩ)
239.5	5.70	NA

4-2. 8-bit ADC Performance

Parameter	Description	Conditions	Min	Typ	Max	Unit
ENOB	Effective number of bits	$f_{ADC} = 14 \text{ MHz}$ $V_{DDA} = V_{REF+} = 3.3 \text{ V}$ Input Frequency = 20 kHz Temperature = 25		10.3		bits
SNDR	Signal-to-noise and distortion ratio			63.8		dB
SNR	Signal-to-noise ratio			64.5		
THD	Total harmonic distortion			-67.5		

(1) Based on characterization, not tested in production.

4-2. 9-bit ADC Performance

Parameter	Description	Conditions	Min	Typ	Max	Unit
ENOB	Effective number of bits	$f_{ADC} = 42 \text{ MHz}$ $V_{DDA} = V_{REF+} = 3.3 \text{ V}$ Input Frequency = 20 kHz Temperature = 25		10.3		bits
SNDR	Signal-to-noise and distortion ratio			63.8		dB
SNR	Signal-to-noise ratio			64.5		
THD	Total harmonic distortion			-67.5		

(1) Based on characterization, not tested in production.

4-0. 9-bit Linearity Error

Parameter	Description	Conditions	Min	Max	Unit
Offset	Offset error	$f_{ADC} = 42 \text{ MHz}$ $V_{DDA} = V_{REF+} = 3.3 \text{ V}$		±1	LSB
DNL	Differential linearity error			±1	
INL	Integral linearity error			±3	

(1) Based on characterization, not tested in production.

4. Temperature Sensor

4-3. Temperature Sensor Performance

Parameter	Description	Min	Typ	Max	Unit
T_L	VSENSE linearity with temperature		±1.5		
Avg_Slope	Average slope		4.3		mV/
V_{25}	Voltage at 25 °C		1.47		V
t_{START}	Startup time				s
$t_{S_temp}^{(2)}$	ADC sampling time when reading the temperature		17.1		s

(1) Based on characterization, not tested in production.

(2) Shortest sampling time can be determined in the application by multiple iterations.

4. DAC

4-2. DAC Performance

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{DDA}^{(1)}$	Operating voltage		1.71	3.3	3.6	V
$V_{REF+}^{(1)}$	Reference supply voltage		1.8		V_{DDA}	V
$V_{REF-}^{(1)}$	Negative Reference Voltage			V_{SSA}		V
$R_{LOAD}^{(2)}$	Load resistance	Resistive load with buffer ON	5			
$R_o^{(2)}$	Impedance output with buffer OFF				15	
$C_{LOAD}^{(2)}$	Load capacitance	No pin/pad capacitance included			50	pF
DAC_OUT min ⁽²⁾	Lower DAC_OUT voltage with buffer ON		0.2			V
DAC_OUT max ⁽²⁾	Higher DAC_OUT voltage with buffer ON				$V_{DDA} - 0.2$	V
DAC_OUT min ⁽²⁾	Lower DAC_OUT voltage with buffer OFF			0.5		mV
DAC_OUT max ⁽²⁾	Higher DAC_OUT voltage with buffer OFF				$V_{DDA} - 1LSB$	V
$I_{DDA}^{(1)}$	DAC current consumption in quiescent mode	With no load, middle code(0x800) on the input, $V_{REF+} = 3.6 V$		380		A
		With no load, worst code(0xF1C) on the input, $V_{REF+} = 3.6 V$		460		A
$I_{DDVREF+}^{(1)}$	DAC current consumption in quiescent mode	With no load, middle code(0x800) on the input, $V_{REF+} = 3.6 V$		120		A
		With no load, worst code(0xF1C) on the input, $V_{REF+} = 3.6 V$		320		A
DNL ⁽¹⁾	Differential non-linearity error	DAC in 12-bit mode			± 3	LSB
INL ⁽¹⁾	Integral non-linearity	DAC in 12-bit mode			± 4	LSB
Offset ⁽¹⁾	Offset error	DAC in 12-bit mode			± 12	LSB
GE ⁽¹⁾	Gain error	DAC in 12-bit mode			± 0.5	%
$T_{setting}^{(1)}$	Settling time	$C_{LOAD} = 50 pF, R_{LOAD} = 5 k$		0.3	1	
$t_{wakeup}^{(2)}$	Wakeup from off state			5	10	s
Update rate ⁽²⁾	Max frequency for a correct DAC_OUT change from code i to $i \pm 1LSBs$	$C_{LOAD} = 50 pF, R_{LOAD} = 5 k$			4	MS/s
PSRR ⁽²⁾	Power supply rejection ratio		55	80		dB

Symbol	Parameter	Unit	Min	Typ	Max	Unit
	(to V_{DDA})					

- (1) Based on characterization, not tested in production.
(2) Guaranteed by design, not tested in production.

4.2.6

Table 4-3.2 (1)

Symbol	Parameter	Unit	Min		Max		Min		Unit
			M	M	M	M	M	M	
$t_{SCL(H)}$	SCL clock high time		4.0		0.6		0.2		s
$t_{SCL(L)}$	SCL clock low time		4.7		1.3		0.5		s
$t_{su(SDA)}$	SDA setup time		2		0.8		0.1		s
$t_h(SDA)$	SDA data hold time		250		250		130		ns
$t_r(SDA/SCL)$	SDA and SCL rise time			1000	20	300		120	ns
$t_f(SDA/SCL)$	SDA and SCL fall time		4	300	4	300	4	120	ns
$t_h(STA)$	Start condition hold time		4.0		0.6		0.26		s

- (1) Guaranteed by design, not tested in production
(2) Test condition: GPIO_SPEED set 2 MHz and external pull-up resistor value is 1 Ω when operate EEPROM with I2C.

4.2.7

Table 4-3.3 (1)

Symbol	Parameter	Unit	Min	Typ	Max	Unit
f_{SCK}	SCK clock frequency				30	MHz
$t_{SCK(H)}$	SCK clock high time	Master mode, $f_{PCLKx} = 120$ MHz, presc = 8	31.83	33.33	34.83	ns
$t_{SCK(L)}$	SCK clock low time	Master mode, $f_{PCLKx} = 120$ MHz, presc = 8	31.83	33.33	34.83	ns
SP mode						
$t_{V(MO)}$	Data output valid time			7		ns
$t_{H(MO)}$	Data output hold time			4		ns
$t_{SU(MI)}$	Data input setup time		1			ns
$t_{H(MI)}$	Data input hold time		0			ns
BS mode						
$t_{SU(NSS)}$	NSS enable setup time		0			ns
$t_{H(NSS)}$	NSS enable hold time		1			ns
$t_{A(SO)}$	Data output access time			9		ns
$t_{DIS(SO)}$	Data output disable time			8		ns

$t_{V(SO)}$	Data output valid time		10	ns
$t_{H(SO)}$	Data output hold time		10	ns
$t_{SU(SI)}$	Data input setup time	0		ns
$t_{H(SI)}$	Data input hold time	2		ns

(1) Based on characterization, not tested in production.

4. 2.8.5.

Table 4-5.2.5 (1) (2)

Symbol	Parameter	Mode	Min	Typ	Max	Unit
f_{CK}	Clock frequency	Master mode (data: 16 bits, Audio frequency = 96 kHz)		3.078		MHz
		Slave mode		10		
t_H	Clock high time			162		ns
t_L	Clock low time			163		ns
$t_{V(WS)}$	WS valid time	Master mode		2		ns
$t_{H(WS)}$	WS hold time	Master mode		2		ns
$t_{SU(WS)}$	WS setup time	Slave mode	0			ns
$t_{H(WS)}$	WS hold time	Slave mode	3			ns
$DuCy_{(SCK)}$	I2S slave input clock duty cycle	Slave mode		50		%
$t_{SU(SD_MR)}$	Data input setup time	Master mode	0			ns
$t_{su(SD_SR)}$	Data input setup time	Slave mode	0			ns
$t_{H(SD_MR)}$	Data input hold time	Master receiver	1			ns
$t_{H(SD_SR)}$		Slave receiver	3			ns
$t_{V(SD_ST)}$	Data output valid time	Slave transmitter (after enable edge)		12		ns
$t_{H(SD_ST)}$	Data output hold time	Slave transmitter (after enable edge)		10		ns
$t_{V(SD_MT)}$	Data output valid time	Master transmitter (after enable edge)		10		ns
$t_{H(SD_MT)}$	Data output hold time	Master transmitter (after enable edge)		7		ns

(1) Guaranteed by design, not tested in production.

(2) Based on characterization, not tested in production.

4. 2.9.6.

Table 4-6.6 (1)

Symbol	Parameter	Mode	Min	Typ	Max	Unit
f_{SCK}	SCK clock frequency	$f_{PCLKx} = 120$ MHz			60	MHz
$t_{SCK(H)}$	SCK clock high time	$f_{PCLKx} = 120$ MHz	7.5			ns

$t_{SCK(L)}$	SCK clock low time	$f_{PCLKx} = 120 \text{ MHz}$	7.5			ns
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(1) Guaranteed by design, not tested in production.

4.2.0

Refer to [Table 4-24. I/O port DC characteristics](#)⁽¹⁾ for more details on the input/output alternate function characteristics (CANTX and CANRX).

4.2.1

4-3. USBFS

Symbol	Parameter	Min	Max
$t_{STARTUP}^{(1)}$	USBFS startup time	1	s

(1) Guaranteed by design, not tested in production.

4-8. USB I/O

Symbol	Parameter	Min	Typ	Max	Unit
Input levels ⁽¹⁾	V_{DD}	USBFS operating voltage		3	3.6
	V_{DI}	Differential input sensitivity		0.2	
	V_{CM}	Differential common mode range		0.8	2.5
	V_{SE}	Single ended receiver threshold		1.3	2.0
Output levels ⁽²⁾	V_{OL}	Static output level low		R_L of 1.0 to 3.6 V	0.064 0.3
	V_{OH}	Static output level high		R_L of 15 to VSS	2.8 3.3 3.6
$R_{PD}^{(2)}$	PA11, PA12(USB_DM/DP)		$V_{IN} = V_{DD}$	17	20.574 24
	PA9(USB_VBUS)			0.65	2.0
$R_{PU}^{(2)}$	PA11, PA12(USB_DM/DP)		$V_{IN} = V_{SS}$	1.5	1.585 2.1
	PA9(USB_VBUS)			0.25	0.326 0.55

(1) Guaranteed by design, not tested in production.

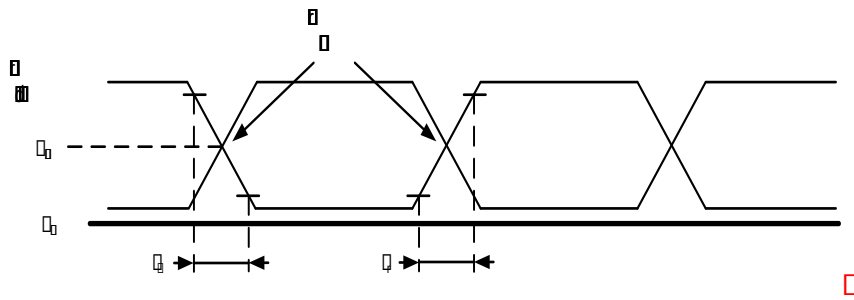
(2) Based on characterization, not tested in production.

4-9. USB Timing (1)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
t_R	Rise time	$C_L = 50 \text{ pF}$	4		20	ns
t_F	Fall time	$C_L = 50 \text{ pF}$	4		20	ns
t_{RFM}	Rise/fall time matching	t_R/t_F	90		110	%
V_{CRS}	Output signal crossover voltage		1.3		2.0	V

(1) Guaranteed by design, not tested in production.

4-6. USB Timing



4 . 2 . 2 .

4-4 . 0

(1) 2 i p 4)

Symbol	Description	M	M	Unit
$t_{w(NE)}$	EXMC_NE low time	40.5	42.5	ns
$t_{v(NOE_NE)}$	EXMC_NEx low to EXMC_NOE low	0		ns
$t_{w(NOE)}$	EXMC_NOE low time	40.5	42.5	ns
$t_{h(NE_NOE)}$	EXMC_NOE high to EXMC_NE high hold time	0		ns
$t_{v(A_NE)}$	EXMC_NEx low to EXMC_A valid	0		ns
$t_{v(BL_NE)}$	EXMC_NEx low to EXMC_BL valid	0		ns
$t_{su(DATA_NE)}$	Data to EXMC_NEx high setup time	32.2		ns
$t_{su(DATA_NOE)}$	Data to EXMC_NOEx high setup time	32.2		ns
$t_{h(DATA_NOE)}$	Data hold time after EXMC_NOE high	0		ns
$t_{h(DATA_NE)}$	Data hold time after EXMC_NEx high	0		ns
$t_{v(NADV_NE)}$	EXMC_NEx low to EXMC_NADV low	0		ns
$t_{w(NADV)}$	EXMC_NADV low time	7.3	9.3	ns

- (1) $C_L = 30$ pF.
- (2) Guaranteed by design, not tested in production.
- (3) Based on characterization, not tested in production.
- (4) Based on configure: $f_{HCLK} = 120$ MHz, AddressSetupTime = 0, AddressHoldTime = 1, DataSetupTime = 1.

4-4 . 1

(() 2 i p 4)

Symbol	Description	M	M	Unit
$t_{w(NE)}$	EXMC_NE low time	23.9	25.9	ns
$t_{v(NWE_NE)}$	EXMC_NEx low to EXMC_NWE low	7.3		ns
$t_{w(NWE)}$	EXMC_NWE low time	7.3	9.3	ns
$t_{h(NE_NWE)}$	EXMC_NWE high to EXMC_NE high hold time	7.3	9.3	ns
$t_{v(A_NE)}$	EXMC_NEx low to EXMC_A valid	0		ns
$t_{v(NADV_NE)}$	EXMC_NEx low to EXMC_NADV low	0		ns
$t_{w(NADV)}$	EXMC_NADV low time	7.3	9.3	ns
$t_{h(AD_NADV)}$	EXMC_AD(address) valid hold time after EXMC_NADV high	15.6		ns
$t_{h(A_NWE)}$	Address hold time after EXMC_NWE high	7.3		ns
$t_{h(BL_NWE)}$	EXMC_BL hold time after EXMC_NWE high	7.3		ns

$t_{v(BL_NE)}$	EXMC_NEx low to EXMC_BL valid	0		ns
$t_{v(DATA_NADV)}$	EXMC_NADV high to DATA valid	0		ns
$t_{h(DATA_NWE)}$	Data hold time after EXMC_NWE high	7.3		ns

- (1) $C_L = 30$ pF.
- (2) Guaranteed by design, not tested in production.
- (3) Based on characterization, not tested in production.
- (4) Based on configure: 120 MHz, AddressSetupTime = 0, AddressHoldTime = 1, DataSetupTime = 1.

4-4 . 2

(1) (2 | 4)

t	t	M	M	t
$t_{w(NE)}$	EXMC_NE low time	57.1	59.1	ns
$t_{v(NO_NE)}$	EXMC_NEx low to EXMC_NOE low	23.9		ns
$t_{w(NO)}$	EXMC_NOE low time	32.2	34.2	ns
$t_{h(NE_NO)}$	EXMC_NOE high to EXMC_NE high hold time	0		ns
$t_{v(A_NE)}$	EXMC_NEx low to EXMC_A valid	0		ns
$t_{v(A_NO)}$	Address hold time after EXMC_NOE high	0		ns
$t_{v(BL_NE)}$	EXMC_NEx low to EXMC_BL valid	0		ns
$t_{h(BL_NO)}$	EXMC_BL hold time after EXMC_NOE high	0		ns
$t_{su(DATA_NE)}$	Data to EXMC_NEx high setup time	33.2		ns
$t_{su(DATA_NO)}$	Data to EXMC_NOEx high setup time	33.2		ns
$t_{h(DATA_NO)}$	Data hold time after EXMC_NOE high	0		ns
$t_{h(DATA_NE)}$	Data hold time after EXMC_NEx high	0		ns
$t_{v(NADV_NE)}$	EXMC_NEx low to EXMC_NADV low	0		ns
$t_{w(NADV)}$	EXMC_NADV low time	7.3	9.3	ns
$T_{h(AD_NADV)}$	EXMC_AD(address) valid hold time after EXMC_NADV high	7.3	9.3	ns

- (1) $C_L = 30$ pF.
- (2) Guaranteed by design, not tested in production.
- (3) Based on characterization, not tested in production.
- (4) Based on configure: $f_{HCLK} = 120$ MHz, AddressSetupTime = 0, AddressHoldTime = 1, DataSetupTime = 1.

4-4 . 3

(1) (2 | 4)

t	t	M	M	t
$t_{w(NE)}$	EXMC_NE low time	40.5	42.5	ns
$t_{v(NWE_NE)}$	EXMC_NEx low to EXMC_NWE low	7.3		ns
$t_{w(NWE)}$	EXMC_NWE low time	23.9	25.9	ns
$t_{h(NE_NWE)}$	EXMC_NWE high to EXMC_NE high hold time	7.3		ns
$t_{v(A_NE)}$	EXMC_NEx low to EXMC_A valid	0		ns
$t_{v(NADV_NE)}$	EXMC_NEx low to EXMC_NADV low	0		ns
$t_{w(NADV)}$	EXMC_NADV low time	7.3	9.3	ns
$t_{h(AD_NADV)}$	EXMC_AD(address) valid hold time after EXMC_NADV high	7.3		ns
$t_{h(A_NWE)}$	Address hold time after EXMC_NWE high	7.3		ns
$t_{h(BL_NWE)}$	EXMC_BL hold time after EXMC_NWE high	7.3		ns
$t_{v(BL_NE)}$	EXMC_NEx low to EXMC_BL valid	0		ns

$t_v(\text{DATA_NADV})$	EXMC_NADV high to DATA valid	7.3		ns
$t_h(\text{DATA_NWE})$	Data hold time after EXMC_NWE high	7.3		ns

- (1) $C_L = 30$ pF.
- (2) Guaranteed by design, not tested in production.
- (3) Based on characterization, not tested in production.
- (4) Based on configure: $f_{\text{HCLK}} = 120$ MHz, AddressSetupTime = 0, AddressHoldTime = 1, DataSetupTime = 1.

4-4 . 4

(1)(2 I P 4)

Symbol	Description	Min	Max	Unit
$t_w(\text{CLK})$	EXMC_CLK period	33.2		ns
$t_d(\text{CLKL-NExL})$	EXMC_CLK low to EXMC_NEx low	0		ns
$t_d(\text{CLKH-NExH})$	EXMC_CLK high to EXMC_NEx high	15.6		ns
$t_d(\text{CLKL-NADV})$	EXMC_CLK low to EXMC_NADV low	0		ns
$t_d(\text{CLKL-NADVH})$	EXMC_CLK low to EXMC_NADV high	0		ns
$t_d(\text{CLKL-AV})$	EXMC_CLK low to EXMC_Ax valid	0		ns
$t_d(\text{CLKH-AIV})$	EXMC_CLK high to EXMC_Ax invalid	15.6		ns
$t_d(\text{CLKL-NOEL})$	EXMC_CLK low to EXMC_NOE low	0		ns
$t_d(\text{CLKH-NOEH})$	EXMC_CLK high to EXMC_NOE high	15.6		ns
$t_d(\text{CLKL-ADV})$	EXMC_CLK low to EXMC_AD valid	0		ns
$t_d(\text{CLKL-ADIV})$	EXMC_CLK low to EXMC_AD invalid	0		ns

- (1) $C_L = 30$ pF.
- (2) Guaranteed by design, not tested in production.
- (3) Based on characterization, not tested in production.
- (4) Based on configure: $f_{\text{HCLK}} = 120$ MHz, BurstAccessMode = Enable; Memory Type = PSRAM; WriteBurst = Enable; CLKDivision = 3 (EXMC_CLK is 4 divided by HCLK); Data Latency = 1.

4-4 . 5

(1)(2 I P 4)

Symbol	Description	Min	Max	Unit
$t_w(\text{CLK})$	EXMC_CLK period	33.2		ns
$t_d(\text{CLKL-NExL})$	EXMC_CLK low to EXMC_NEx low	0		ns
$t_d(\text{CLKH-NExH})$	EXMC_CLK high to EXMC_NEx high	15.6		ns
$t_d(\text{CLKL-NADV})$	EXMC_CLK low to EXMC_NADV low	0		ns
$t_d(\text{CLKL-NADVH})$	EXMC_CLK low to EXMC_NADV high	0		ns
$t_d(\text{CLKL-AV})$	EXMC_CLK low to EXMC_Ax valid	0		ns
$t_d(\text{CLKH-AIV})$	EXMC_CLK high to EXMC_Ax invalid	15.6		ns
$t_d(\text{CLKL-NWEL})$	EXMC_CLK low to EXMC_NWE low	0		ns
$t_d(\text{CLKH-NWEH})$	EXMC_CLK high to EXMC_NWE high	15.6		ns
$t_d(\text{CLKL-ADIV})$	EXMC_CLK low to EXMC_AD invalid	0		ns
$t_d(\text{CLKL-DATA})$	EXMC_A/D valid data after EXMC_CLK low	0		ns
$t_h(\text{CLKL-NBLH})$	EXMC_CLK low to EXMC_NBL high	0		ns

- (1) $C_L = 30$ pF.
- (2) Guaranteed by design, not tested in production.
- (3) Based on characterization, not tested in production.
- (4) Based on configure: $f_{\text{HCLK}} = 120$ MHz, BurstAccessMode = Enable; MemoryType = PSRAM; WriteBurst = Enable; CLKDivision = 3 (EXMC_CLK is 4 divided by HCLK); DataLatency = 1.

4-4 . 6

(1)(2 I P 4)

Symbol	Description	Min	Max	Unit
$t_w(\text{CLK})$	EXMC_CLK period	33.2		ns
$t_d(\text{CLKL-NExL})$	EXMC_CLK low to EXMC_NEx low	0		ns
$t_d(\text{CLKH-NExH})$	EXMC_CLK high to EXMC_NEx high	15.6		ns
$t_d(\text{CLKL-NADVl})$	EXMC_CLK low to EXMC_NADV low	0		ns
$t_d(\text{CLKL-NADVh})$	EXMC_CLK low to EXMC_NADV high	0		ns
$t_d(\text{CLKL-AV})$	EXMC_CLK low to EXMC_Ax valid	0		ns
$t_d(\text{CLKH-AIV})$	EXMC_CLK high to EXMC_Ax invalid	15.6		ns
$t_d(\text{CLKL-NOEL})$	EXMC_CLK low to EXMC_NOE low	0		ns
$t_d(\text{CLKH-NOEH})$	EXMC_CLK high to EXMC_NOE high	15.6		ns

- (1) $C_L = 30$ pF.
- (2) Guaranteed by design, not tested in production.
- (3) Based on characterization, not tested in production.
- (4) Based on configure: $f_{\text{HCLK}} = 120$ MHz, BurstAccessMode = Enable; MemoryType = PSRAM; WriteBurst = Enable; CLKDivision = 3 (EXMC_CLK is 4 divided by HCLK); DataLatency = 1.

4-4.7

Symbol	Description	Min	Max	Unit
$t_w(\text{CLK})$	EXMC_CLK period	33.2		ns
$t_d(\text{CLKL-NExL})$	EXMC_CLK low to EXMC_NEx low	0		ns
$t_d(\text{CLKH-NExH})$	EXMC_CLK high to EXMC_NEx high	15.6		ns
$t_d(\text{CLKL-NADVl})$	EXMC_CLK low to EXMC_NADV low	0		ns
$t_d(\text{CLKL-NADVh})$	EXMC_CLK low to EXMC_NADV high	0		ns
$t_d(\text{CLKL-AV})$	EXMC_CLK low to EXMC_Ax valid	0		ns
$t_d(\text{CLKH-AIV})$	EXMC_CLK high to EXMC_Ax invalid	15.6		ns
$t_d(\text{CLKL-NWEL})$	EXMC_CLK low to EXMC_NWE low	0		ns
$t_d(\text{CLKH-NWEH})$	EXMC_CLK high to EXMC_NWE high	15.6		ns
$t_d(\text{CLKL-DATA})$	EXMC_A/D valid data after EXMC_CLK low	0		ns
$t_h(\text{CLKL-NBLH})$	EXMC_CLK low to EXMC_NBL high	0		ns

- (1) $C_L = 30$ pF.
- (2) Guaranteed by design, not tested in production.
- (3) Based on characterization, not tested in production.
- (4) Based on configure: $f_{\text{HCLK}} = 120$ MHz, BurstAccessMode = Enable; MemoryType = PSRAM; WriteBurst = Enable; CLKDivision = 3 (EXMC_CLK is 4 divided by HCLK); DataLatency = 1.

4.2.3

4-4.8

Symbol	Description	Min	Max	Unit
t_{res}	Timer resolution time		1	$t_{\text{TIMERxCLK}}$
		$f_{\text{TIMERxCLK}} = 120$ MHz	8.4	ns
f_{EXT}	Timer external clock frequency		0	$f_{\text{TIMERxCLK}}/2$ MHz
		$f_{\text{TIMERxCLK}} = 120$ MHz	0	60 MHz
RES	Timer resolution		16	bit
t_{COUNTER}	16-bit counter clock period	1	65536	$t_{\text{TIMERxCLK}}$

	when internal clock is selected	$f_{\text{TIMERxCLK}} = 120 \text{ MHz}$	0.0084	546	
$t_{\text{MAX_COUNT}}$	Maximum possible count			65536x65536	$t_{\text{TIMERxCLK}}$
		$f_{\text{TIMERxCLK}} = 120 \text{ MHz}$		35.7	s

(1) Guaranteed by design, not tested in production.

4. 2.4

4-4.9 Waveform 0 (zero) K

Prescaler	Bit	Period (ns)	Period (μs)	Unit
1/4	000	0.1	409.6	ms
1/8	001	0.2	819.2	
1/16	010	0.4	1638.4	
1/32	011	0.8	3276.8	
1/64	100	1.6	6553.6	
1/128	101	3.2	13107.2	
1/256	110 or 111	6.4	26214.4	

(1) Guaranteed by design, not tested in production.

4-6. Waveform 0 M (f) ()

Prescaler	Bit	Period (ns)	Unit	Period (μs)	Unit
1/1	00	68.27	s	4.37	ms
1/2	01	136.53		8.74	
1/4	10	273.07		17.48	
1/8	11	546.13		34.96	

(1) Guaranteed by design, not tested in production.

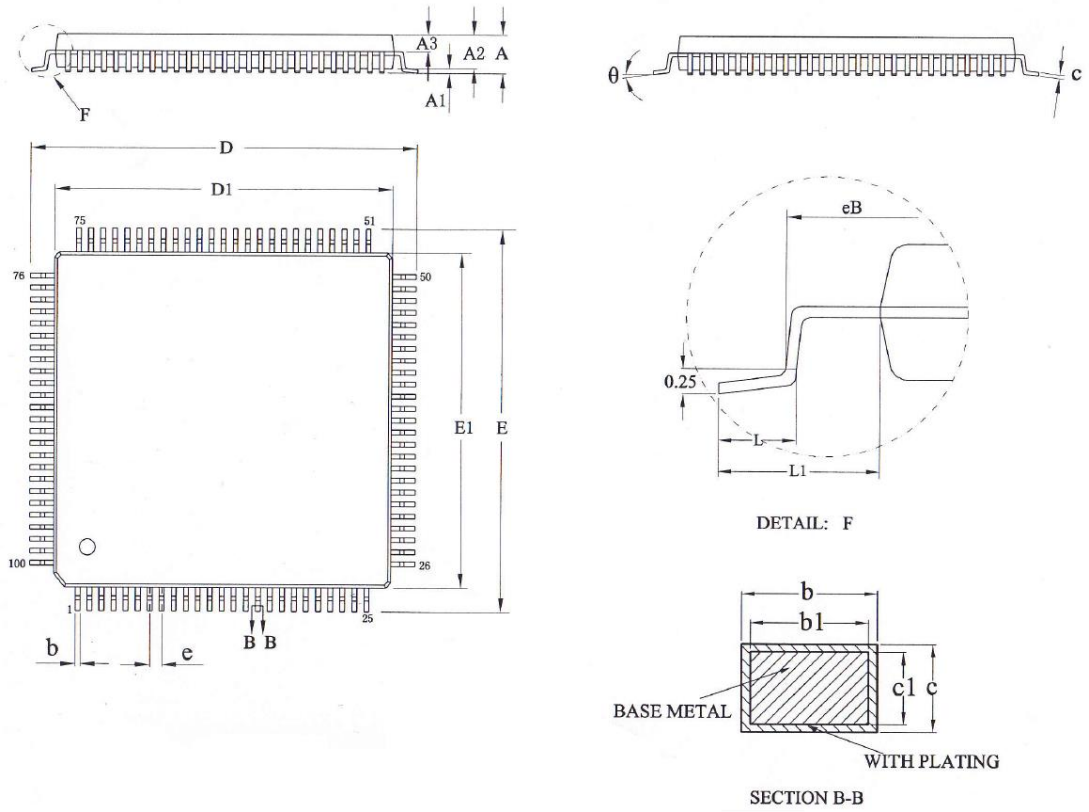
4. 2.5

Unless otherwise specified, all values given for $V_{\text{DD}} = V_{\text{DDA}} = 3.3 \text{ V}$, $T_{\text{A}} = 25$.

5 

5 1  OP 

F  5-1.  



5 5-1.  OP 

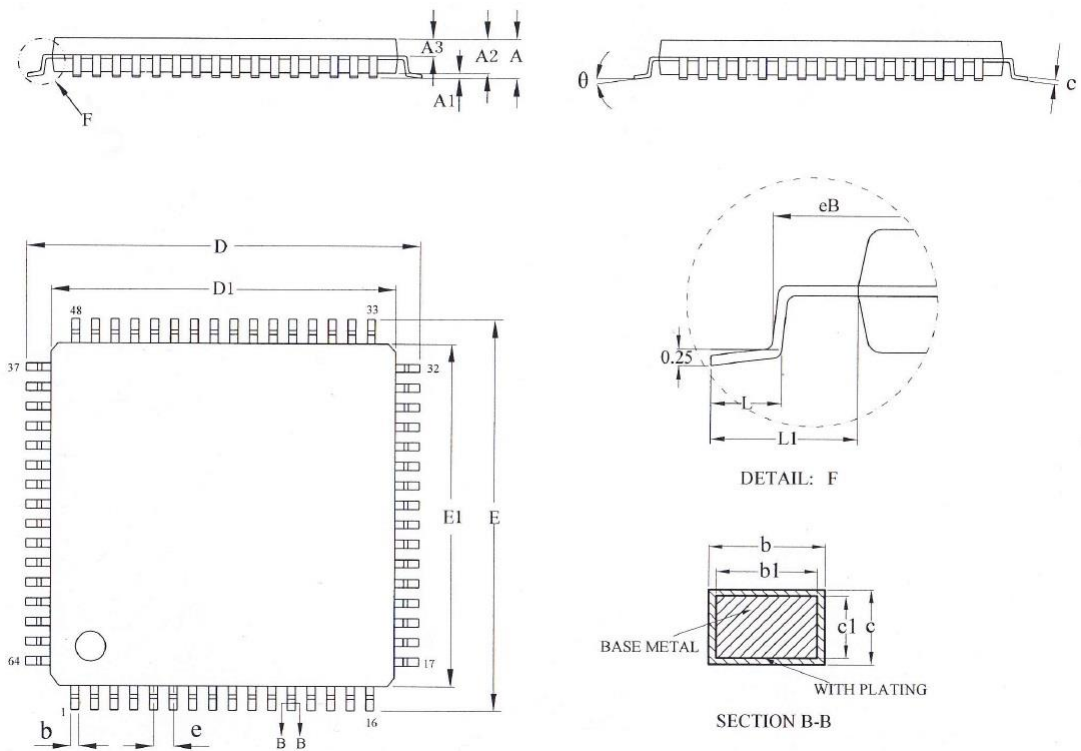
Symbol	M	Symbol	M
A			1.60
A1	0.05		0.15
A2	1.35	1.40	1.45
A3	0.59	0.64	0.69
D	15.80	16.0	16.20
D1	13.90	14.0	14.10
E	15.80	16.0	16.20
E1	13.90	14.0	14.10
	0°	3.5°	7°
c	0.13		0.17
c1	0.12	0.13	0.14
L	0.45	0.6	0.75
L1		1.0REF	

Symbol	M	J	M
b	0.18	0.20	0.26
b1	0.17	0.20	0.23
eB	15.05		15.35
e		0.50BSC	

(Original dimensions are in millimeters)

5 2 Q . 6 P 4

F 5-2. Q 6 P 4



5-2. Q 6 P 4

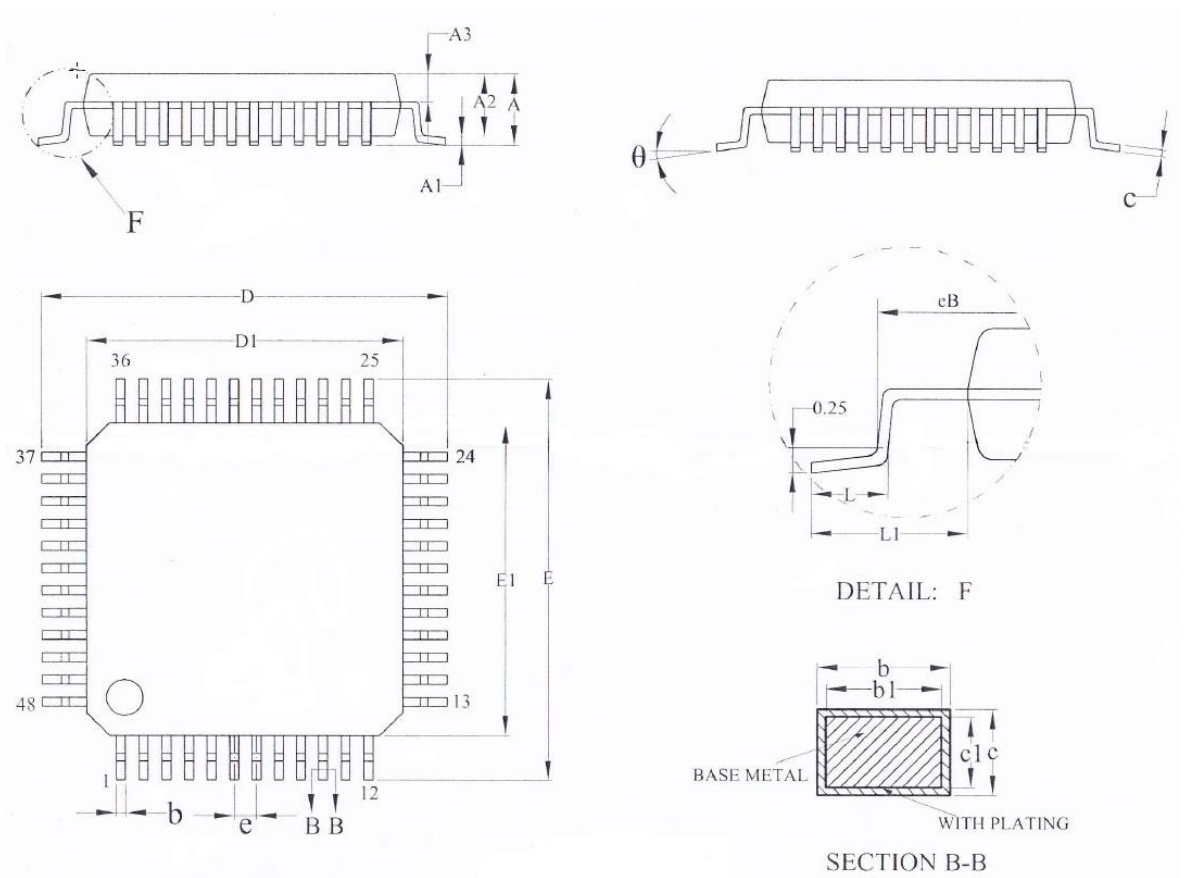
Symbol	M	J	M
A			1.60
A1	0.05		0.15
A2	1.35	1.40	1.45
A3	0.59	0.64	0.69
D	11.80	12.00	12.20
D1	9.90	10.00	10.10
E	11.80	12.00	12.20
E1	9.90	10.00	10.10
	0°	3.5°	7°
c	0.13		0.17

Symbol	M	P	M
L	0.45	0.60	0.75
L1		1.00REF	
b	0.17	0.20	0.27
e		0.50BSC	
eB	11.25		11.45

(Original dimensions are in millimeters)

5 3 Q 4 P 8

F 5-3. Q 4 P 8



5-3. Q 4 P 8

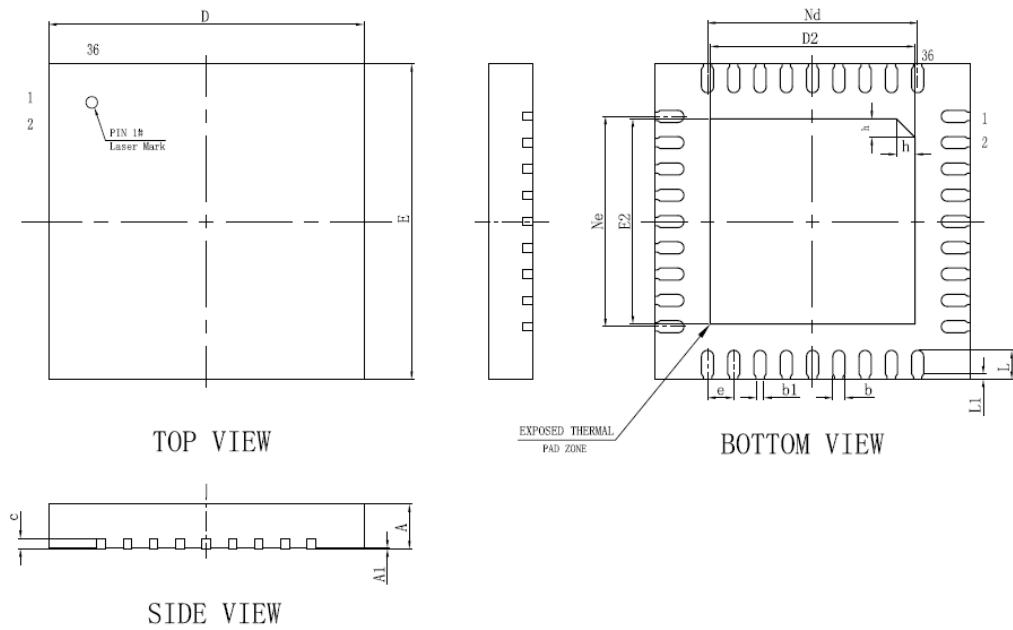
Symbol	M	P	M
A			1.60
A1	0.05		0.15
A2	1.35	1.40	1.45
A3	0.59	0.64	0.69
b	0.18		0.26
b1	0.17	0.20	0.23
c	0.13		0.17

c1	0.12	0.13	0.14
D	8.80	9.00	9.20
D1	6.90	7.00	7.10
E	8.80	9.00	9.20
eB	8.10		8.25
E1	6.90	7.00	7.10
e	0.50BSC		
L	0.45		0.75
L1	1.00REF		
	0		7°

(Original dimensions are in millimeters)

5 4 2 . 3

F 5-4. 2 3 4



□

□

□ □

5-4. 6

Symbol	Min	Typ	Max
A	0.8	0.85	0.90
A1	0.00	0.02	0.05
b	0.18	0.23	0.30
b1	0.16REF		
c	0.18	0.20	0.23
D	5.90	6.00	6.10
D2	3.80	3.90	4.00
Nd	3.95	4.00	4.05
e	0.50BSC		
E	5.90	6.00	6.10
E2	3.80	3.90	4.00
Ne	3.95	4.00	4.05
L	0.50	0.55	0.60
L1	0.10REF		
h	0.30	0.35	0.40

(Original dimensions are in millimeters)

1.

1. Formed lead shall be planar with respect to one another within 0.004 inches.
2. Both package length and width do not include mold flash and metal burr.

5 Thermal

Thermal resistance is used to characterize the thermal performance of the package device, which is represented by R_{JA} , R_{JB} , R_{JC} , θ_{JB} , θ_{JT} . R_{JA} represents the steady-state temperature rise of the chip junction due to the heat dissipated on the chip surface.

« R_{JA} : Thermal resistance, junction-to-ambient.

« R_{JB} : Thermal resistance, junction-to-board.

« R_{JC} : Thermal resistance, junction-to-case.

° θ_{JB} : Thermal characterization parameter, junction-to-board.

° θ_{JT} : Thermal characterization parameter, junction-to-top center.

$$\text{« } R_{JA} = (T_J - T_A)/P_D$$

$$\text{« } R_{JB} = (T_J - T_B)/P_D$$

$$\text{« } R_{JC} = (T_J - T_C)/P_D$$

Where, T_J = Junction temperature.

T_A = Ambient temperature

T_B = Board temperature

T_C = Case temperature which is monitoring on package surface

P_D = Total power dissipation

« R_{JA} represents the resistance of the heat flows from the heating junction to ambient air. It is

an indicator of package heat dissipation capability. Lower θ_{JA} can be considered as better overall thermal performance. θ_{JA} is generally used to estimate junction temperature. θ_{JB} is used to measure the heat flow resistance between the chip surface and the PCB board. θ_{JC} represents the thermal resistance between the chip surface and the package top case. θ_{JC} is mainly used to estimate the heat dissipation of the system (using heat sink or other heat dissipation methods outside the device package).

5-5. Thermal Characteristics

Symbol	Condition	Package	Value	Unit
θ_{JA}	$T_A = 85^\circ\text{C}$, Natural convection, 2S2P PCB	LQFP100	49.18	C/W
		LQFP64	54.57	
		LQFP48	69.64	
		QFN36	36.82	
θ_{JB}	$T_A = 25^\circ\text{C}$, Cold plate, 2S2P PCB	LQFP100	22.70	C/W
		LQFP64	35.08	
		LQFP48	43.16	
		QFN36	9.79	
θ_{JC}	$T_A = 25^\circ\text{C}$, Cold plate, 2S2P PCB	LQFP100	12.52	C/W
		LQFP64	18.11	
		LQFP48	25.36	
		QFN36	13.31	
θ_{JB}	$T_A = 85^\circ\text{C}$, Natural convection, 2S2P PCB	LQFP100	32.85	C/W
		LQFP64	35.41	
		LQFP48	47.75	
		QFN36	9.87	
θ_{JT}	$T_A = 85^\circ\text{C}$, Natural convection, 2S2P PCB	LQFP100	0.53	C/W
		LQFP64	1.10	
		LQFP48	2.45	
		QFN36	0.43	

(1) Thermal characteristics are based on simulation, and meet JEDEC specification.

6. Environmental Characteristics

6-1. Environmental Characteristics

Part Number	Pin Count	Package	Color	Operating Temperature Range
GD32E103T8U6	64	QFN36	Green	Industrial -40°C to +85°C
GD32E103TBU6	128	QFN36	Green	Industrial -40°C to +85°C
GD32E103C8T6	64	LQFP48	Green	Industrial -40°C to +85°C
GD32E103CBT6	128	LQFP48	Green	Industrial -40°C to +85°C
GD32E103R8T6	64	LQFP64	Green	Industrial -40°C to +85°C



Part Number	Flash Size	Package	RoHS	Temperature Range
GD32E103RBT6	128	LQFP64	Green	Industrial -40 °C to +85 °C
GD32E103V8T6	64	LQFP100	Green	Industrial -40 °C to +85 °C
GD32E103VBT6	128	LQFP100	Green	Industrial -40 °C to +85 °C

7



h3

7-1. Revision History

Version	Description	Date
1.0	Initial Release	Dec. 26, 2017
1.1	Modify section 2.6 Pin definitions	Oct. 29, 2018
1.2	Repair history accumulation error	Dec. 12, 2018
1.3	Modify section 5.1 LQFP package outline dimensions	Apr. 22, 2019
1.4	Modify section 2.6 Pin definitions	Jun. 26, 2019
1.5	Remove redundant pin function in LQFP48 and QFN36 package. Add functional description of PD0 and PD1 to the packages below 100pin. Update electrical characteristics.	Mar. 6, 2020



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